





THVD4431 SLLSFS1B – AUGUST 2023 – REVISED APRIL 2024

THVD4431 Multiprotocol (RS-232, RS-422, RS485) Transceiver with Integrated 120-Ω Switchable Termination Resistor and IEC-ESD Protection

1 Features

TEXAS

INSTRUMENTS

- Meets or exceeds the requirements of the TIA/ EIA-485A and TIA/EIA-232F standards
- 3 transmitters, 5 receivers for RS-232
- 1 transmitter, 1 receiver for RS-485
- On-chip switchable 120Ω termination resistor for RS-485 mode
- Integrated charge-pump for RS-232 signaling
- 3V to 5.5V supply voltage
- 1.65V to 5.5V supply for logic data and control signals
- RS-485 differential output exceeds 2.1V for PROFIBUS compatibility with 5V supply
- Large output swing (typical ± 9V) for RS-232 mode
- SLR Pin Selectable Data Rates:
 - RS-232 3T5R mode: 250kbps and 1Mbps
 - RS-485 half-duplex and full-duplex mode: 500kbps and 20Mbps
- Bus I/O protection
 - ±16kV HBM ESD
 - ±8kV IEC 61000-4-2 contact and ±15kV air-gap discharge
 - ±4kV IEC 61000-4-4 fast transient burst
- Diagnostic loopback for both RS-232 and RS-485 modes
- Shutdown pin for low current consumption (10µA typical) in disabled state
- · Glitch-free power-up/down for hot plug-in capability
- 1/8 unit load (up to 256 bus nodes) for RS-485
- Open, short, and idle bus failsafe for RS-485 receiver
- Bus short-circuit protection, thermal shutdown
- Extended ambient temperature range: -40°C to 125°C
- Space-saving thermally efficient 6mm x 6mm VQFN-40 package

2 Applications

- Industrial PC
- Factory automation and control
- HVAC systems
- Building automation
- Point-of-sale terminals
- Grid infrastructure
- Industrial Transport

3 Description

THVD4431 is a highly integrated and robust Multiprotocol transceiver supporting RS-232, RS-422 and RS-485 physical layers. The device has three transmitters and five receivers to enable 3T5R RS-232 port. The device also integrates one transmitter and one receiver to enable half and full duplex RS-485 port. MODE selection pins enable shared bus and logic pins for the protocols to share a common single connector. Integrated termination for RS-485 bus pins and for RS-232 receiver inputs need no external components to realize a fully-functional communication port. The device has a slew rate select feature that enables it for use at two maximum speeds based on the SLR pin setting.

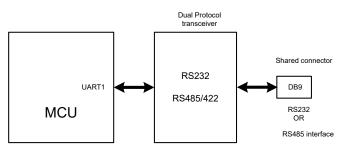
The device features integrated Level 4 IEC ESD protection, eliminating the need for external systemlevel protection components. Diagnostic loopback mode for both RS-232 and RS-485 is provided to check for logic to bus and bus to logic path functional integrity and check for cable and connector shorts. In addition, the RS-485 receiver fail-safe feature drives logic high on received logic output when the bus inputs are open or shorted together or when the bus is idle. Shutdown mode consumes ultra-low current (10µA typical) ideal for power-sensitive applications. The device needs 3 to 5.5V supply that powers the charge pump for RS-232 and the drivers/receivers for both RS-232 and RS-485. A separate logic supply V_{IO} (1.65V to 5.5V) enables interface with low level microcontrollers.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
THVD4431	VQFN (40)	6mm × 6mm

(1) For more information, see Section 11.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



THVD4431 Simplified Schematic



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4 Pin Configuration and Functions

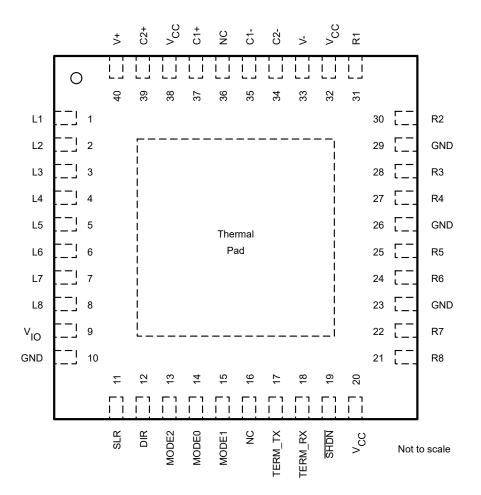


Figure 4-1. 40-Pin VQFN Package (RHA) Top View

Table 4-1. Pin Functions

NAME	NO.	TYPE	DESCRIPTION
L1	1	0	Logic output (RS-232)
L2	2	0	Logic output (RS-232/RS-485)
L3	3	I	Logic input (RS-232/RS-485). Integrated weak pull-up resistor .
L4	4	I	Logic input. Integrated weak pull-up resistor
L5	5	0	Logic output
L6	6	I	Logic input, Integrated weak pull-up resistor
L7	7	0	Logic output
L8	8	0	Logic output
V _{IO}	9	Р	1.65 V to 5.5 V logic supply voltage
GND ⁽¹⁾	10	G	Ground

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			Table 4-1. Pin Functions (continued)
NAME	NO.	TYPE	DESCRIPTION
SLR	11	I	Slew rate control, internal pull-down resistor. SLR=H enables slow speed
DIR	12	I	RS-485 TX/RX enable/disable. Internal pull-down resistor.
MODE2	13	I	
MODE0	14	I	MODE control pins, Integrated weak pull-down resistor
MODE1	15	I	
NC	16	NC	Not connected internally. Can be connected to supply, ground or left open on PCB.
TERM_TX	17	I	120 Ω Termination enable/disable across R1/R2 terminals. Internal Pull down resistor
TERM_RX	18	I	120 Ω Termination enable/disable across R3/R4 terminals. Internal Pull down resistor
SHDN	19	I	Device enable/disable. Internal pull-down resistor
V _{CC}	20	P	3 to 5.5V supply voltage
R8	21	I	RS-232 receiver input
R7	22	I	RS-232 receiver input
GND ⁽¹⁾	23	G	Ground
R6	24	0	RS-232 driver output
R5	25	I	RS-232 receiver input
GND	26	G	Ground
R4	27	I/O	RS-232 driver output or RS-485 inverting receiver input (B)
R3	28	I/O	RS-232 driver output or RS-485 non-inverting receiver input (A)
GND ⁽¹⁾	29	G	Ground
R2	30	I/O	RS-232 receiver input or RS-485 bus pin (Y or A)
R1	31	I/O	RS-232 receiver input or RS-485 bus pin (Z or B)
V _{CC}	32	P	3 to 5.5 V supply voltage
V-	33		Negative charge pump rail
C2-	34		Negative terminal of charge pump capacitor
C1-	35		Negative terminal of charge pump capacitor
NC	36	NC	Not connected internally. Can be left open or Grounded on PCB.
C1+	37		Positive terminal of charge pump capacitor
V _{CC}	38	P	3 to 5.5V supply voltage
C2+	39		Positive terminal of charge pump capacitor
V+	40		Positive charge pump rail

(1) GND pins 10, 23, 26, 29 all must be grounded on PCB.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Bus supply voltage	V _{CC} to GND	-0.5	6	V
Logic supply voltage	V _{IO} to GND	-0.5	V _{CC} + 0.2	V
Charge pump positive-output supply voltage	V+ to GND	-0.3	14	V
Charge pump negative-output supply voltage	V- to GND	-14	0.3	V
Bus voltage	Voltage at any bus pin (R1, R2, R3, R4, R5, R6, R7, R8) with respect to GND	-16	16	V
Differential bus voltage	(R1-R2) or (R2-R1), (R3-R4) or (R4-R3) with termination disbled	-22	22	V
Differential bus voltage RS485 mode	(R1-R2) or (R2-R1), (R3-R4) or (R4-R3) with termination enabled	-6	6	V
Input voltage	Range at any logic pin (L3, L4, L6, SLR, SHDN, TERM_TX, TERM_RX, MODE0, MODE1, MODE2, DIR)	-0.3	V _{IO} + 0.2	V
Receiver output current	I _O (L1, L2, L5, L7, L8)	-8	8	mA
Storage temperature	T _{stg}	-65	150	°C
Junction temperature	TJ	-40	170	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

				VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/	Bus terminals (R1, R2, R3, R4, R5, R6, R7, R8) and GND	±16,000	V
V _(ESD)	Electrostatic discharge	JEDEC JS-001 ⁽¹⁾	All pins except bus terminals and GND	±4,000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾		±1,500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 ESD Ratings [IEC]

					UNIT
Maria		Contact discharge, per IEC 61000-4-2	Bus terminals (R1, R2, R3,	±8,000	V
V _(ESD)	ESD)	Air-gap discharge, per IEC 61000-4-2	R4, R5, R6, R7, R8) and GND	±15,000	
V _(EFT)	Electrical fast transient in RS485 HD or FD mode	Per IEC 61000-4-4	Bus terminals (R1, R2, R3, R4)	±4,000	V



5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		3		5.5	V
V _{IO}	I/O supply voltage		1.65		V _{CC}	V
V _{I (RS-485)}	Input voltage at any bus terminal (F	R1, R2, R3, R4) in RS-485 mode ⁽¹⁾	-7		12	V
V _{ID}	Differential input voltage in RS-485 or (R4-R3)] with on-chip termination	receive mode [(R1-R2) or (R2-R1), (R3-R4) on resistor disabled	-12		12	V
V _{ID}	Differential input voltage in RS-485 or (R4-R3)] with on-chip termination	receive mode [(R1-R2) or (R2-R1), (R3-R4) on resistor enabled	- 5.5		5.5	V
V _{I (RS-232)}	Receiver input voltage in RS-232 n	node	-15		15	V
V _{IH}	High-level input voltage (L3, L4, L6 MODE1, MODE2, DIR inputs)	, SLR, SHDN, TERM_TX, TERM_RX, MODE0,	0.7*V _{IO}		V _{IO}	V
V _{IL}	Low-level input voltage (L3, L4, L6, SLR, SHDN, TERM_TX, TERM_RX, MODE0, MODE1, MODE2, DIR inputs)		0		0.3*V _{IO}	V
I _O	Output current, driver in RS-485 m	ode	-60		60	mA
I _{OR}	Output current, receiver	V _{IO} = 1.8 V or 2.5 V	-2		2	mA
I _{OR}	Output current, receiver	V _{IO} = 3.3 V or 5 V	-4		4	mA
RL	Differential load resistance in RS-4	85 mode	54	60		Ω
	Qianalia a sata in DO 405 and da	SLR = V _{IO}			500	kbps
A 14	Signaling rate in RS-485 mode	SLR = GND or floating			20	Mbps
1/t _{UI}	Qianalia a sata in DO 000 ana da	SLR = V _{IO}			250	kbps
	Signaling rate in RS-232 mode	SLR = GND or floating			1	Mbps
1 /+	Signaling rate in RS-485 loopback	mode			0.5	Mbps
1/t _{UI (loopback)}	Signaling rate in RS-232 loopback	mode			1	Mbps
T _A (2)	Operating ambient temperature		-40		125	°C

The algebraic convention, in which the least positive (most negative) limit is designated as minimum is used in this data sheet.
 Operation is specified for internal (junction) temperatures upto 150°C. Self-heating due to internal power dissipation should be considered for each application. Maximum junction temperature is internally limited by the thermal shut-down (TSD) circuit which disables the driver and receiver when the junction temperature reaches 170°C.

5.5 Thermal Information

		THVD4431	
	THERMAL METRIC ⁽¹⁾	RHA (QFN)	UNIT
		40 PINS	
R _{0JA}	Junction-to-ambient thermal resistance	27.4	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	16.8	°C/W
R _{0JB}	Junction-to-board thermal resistance	9.8	°C/W
ΨJT	Junction-to-top characterization parameter	0.2	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	9.8	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	2.7	°C/W

(1) For more information about traditional and new thermalmetrics, see the Semiconductor and ICPackage Thermal Metrics application report.

5.6 Power Dissipation

	PARAMETER	TEST CONDITIONS			Typical	Max	UNIT
	Full Duplex mode with DIR = V_{10} ,	Unterminated, TERM_TX = L,	SLR = H	500 kbps	160	200	
P _{D (RS-485)}	MODE2, MODE1, MODE0 = 011, R2/R1 are externally connected to	TERM_RX = L	SLR = L	20Mbps	390	450	mW
· D (RS-465)	R3/R4 in loopback fashion; $V_{IO} = V_{CC} = 5.5 \text{ V}, T_A = 125 ^{\circ}\text{C},$	TERM TX = TERM RX = VIO	SLR = H	500 kbps	430	500	mW
	L3 = square wave 50% duty		SLR = L	20Mbps	500	575	11177



5.6 Power Dissipation (continued)

PARAMETER		TEST CONDITIONS			Typical	Max	UNIT
D	RS-232 mode with MODE2, MODE1,	V_{CC} = V_{IO} = 5.5V, R3, R4, R6 bus lines loaded with 3 k Ω , R3 load cap = 1000 pF, L3 toggling		1 Mbps	320	500	mW
P _{D (RS-232)}	MODE0 = 001	V_{CC} = V _{IO} = 5.5V, R3, R4, R6 bus lines loaded with 3 k Ω , R3 load cap = 2500 pF, L3 toggling		250 kbps	185	200	mW

5.7 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted). All typical values are at 25°C and supply voltage of V_{CC} = 5 V, V_{IO} = 3.3 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS		MIN	ТҮР	MAX	UNIT
Driver_R	S-485						
		R_L = 60 Ω , -7 V ≤ V_{test} ≤ 12 V (See Figure 6-1)		1.5	2		V
		R_L = 60 Ω, -7 V ≤ V _{test} ≤ 12 V, 4.5 V ≤ V _{CC} ≤ 5.5 V (S	ee Figure 6-1)	2.1	3		V
V _{OD}	Driver differential output voltage magnitude	$R_L = 100 \Omega$ (See Figure 6-2)		2	2.5		V
		R_L = 54 Ω, 4.5 V ≤ V _{CC} ≤ 5.5 V (See Figure 6-2)		2.1	3.3		V
		$R_L = 54 \Omega$ (See Figure 6-2)		1.5	3.3		V
Δ V _{OD}	Change in magnitude of differential output voltage	R_L = 54 Ω or 100 Ω (See Figure 6-2)		-50		50	mV
V _{OC}	Common-mode output voltage	R_L = 54 Ω or 100 Ω (See Figure 6-2)			V _{CC} /2	3	V
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage	R _L = 54 Ω or 100 Ω (See Figure 6-2)		-50		50	mV
I _{OS}	Short-circuit output current (bus terminals)	DIR = V_{IO} , -7 V ≤ (V_{R2} or V_{R1}) ≤ 12 V, or R1 shorted to	o R2	-250		250	mA
	Driver High impedance output leakage current on	MODE2, MODE1, MODE0 = 011 , TERM_TX = GND, GND or 5.5V, V_0 = -7V, +12V				125	μA
I _{OZD}	R1 and R2 in Full duplex mode	MODE2, MODE1, MODE0 = 011, TERM_TX = V _{IO} , D V _O = -7V, +12V	NR = GND, V _{CC} = 5.5V,	- 325		350	μA
Receiver_	RS-485						
li –	Bus input current (termination disabled)	Half and full duplex modes, DIR = 0 V, V _{CC} and V _{IO} = 0 V or 5.5 V	$V_1 = 12 V$ $V_1 = -7 V$	-125	75 –70	125	μA μA
I _{RXT}	Receiver bus input leakage current with termination enabled	Full duplex mode, V _{CC} and V _{IO} = 5.5 V, TERM_RX = V_{IO}		-325		325	μΑ
V _{TH+}	Positive-going input threshold voltage ⁽¹⁾				- 70	- 40	mV
V _{TH-}	Negative-going input threshold voltage ⁽¹⁾	Over common-mode range of - 7 V to 12 V		-200	-150		mV
V _{HYS}	Input hysteresis	-		25	80		mV
C _{A,B}	Input differential capacitance	Measured between R3 and R4, f = 1 MHz			45		pF
V _{OH}	Output high voltage, L2 pin	I_{OH} = -4 mA, V_{IO} = 3 to 3.6 V or 4.5 V to 5.5 V		V _{IO} - 0.4	$V_{IO} - 0.2$		V
V _{OL}	Output low voltage, L2 pin	I_{OL} = 4 mA, V_{IO} = 3 to 3.6 V or 4.5 V to 5.5 V			0.2	0.4	V
V _{OH}	Output high voltage, L2 pin	$I_{\rm OH}$ = –2 mA, $V_{\rm IO}$ = 1.65 to 1.95 V or 2.25 V to 2.75 V		V _{IO} - 0.4	$V_{IO}-0.2$		V
V _{OL}	Output low voltage, L2 pin	I_{OL} = 2 mA, V_{IO} = 1.65 to 1.95 V or 2.25 V to 2.75 V			0.2	0.4	V
l _{oz}	Output high-impedance current, L2 pin	V_{O} = 0 V or V_{IO} , DIR = VIO, MODE2, MODE1, MODE mode)	E0= 010 (half duplex	-2		2	μA
Driver_R	S-232						
V _{ОН}	High-level output voltage	All DOUT (R3, R4, R6) at R _L = 3 k Ω to GND, DIN (L3 3 V to 3.6 V	, L4, L6) = GND; V _{CC} =	5	5.5	7.2	V
V _{OL}	Low-level output voltage	All DOUT (R3, R4, R6) at R _L = 3 k Ω to GND, DIN (L3 3 V to 3.6 V	, L4, L6) = V _{IO} ; V _{CC} =	-7.2	-5.5	-5	V

5.7 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted). All typical values are at 25°C and supply voltage of V_{CC} = 5 V, V_{IO} = 3.3 V, unless otherwise noted.

	PARAMETER	TE	EST CONDITIONS		MIN	TYP	MAX	UNIT
V _{OH}	High-level output voltage	All DOUT (R3, R4, R6) at R _L = 4.5 V to 5.5 V	= 3 kΩ to GND, DIN (L3	3, L4, L6) = GND; V _{CC} =	7.8	9	11	V
V _{OL}	Low-level output voltage	All DOUT (R3, R4, R6) at R _L = 4.5 V to 5.5 V	= 3 kΩ to GND, DIN (L3	8, L4, L6) = V _{IO} ; V _{CC} =	-11	-9	-7.8	V
l _{os}	Short-circuit output current	V _{CC} = 3.6 V	V _O = 0 V			±35	±60	mA
05	(2)	V _{CC} = 5.5 V	V _O = 0 V			200	200	
r _o	Output resistance on R3, R4, R6	V_{CC} = 0 V, V_+ = 0 V, and V_ = 0 V	$V_{O} = \pm 2 V$		300	10M		Ω
off	Output leakage current on R3, R4, R6	SHDN = GND	$V_0 = \pm 12 V$ $V_0 = \pm 10 V$	$V_{CC} = 3 \text{ to } 3.6 \text{ V}$ $V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$			±125 ±125	μA μA
Receiver	RS-232		10 110 1	V() 1.0 10 0.0 V			1120	P/ 1
(eceivei_	_1(0-202	$I_{OH} = -4 \text{ mA}, V_{IO} = 3 \text{ to } 3.6 \text{ V}$	r 4 5 V to 5 5 V		V 0.5	V _{IO} – 0.2		V
V _{OH}	High-level output voltage L1/L2/L5/L7/L8	$I_{OH} = -2$ mA, $V_{IO} = 3.03.0$ V $I_{OH} = -2$ mA, $V_{IO} = 1.65$ to 1.9		/	-	$V_{IO} - 0.2$ $V_{IO} - 0.2$		v
	Low-level output	I _{OI} = 4 mA, V _{IO} = 3 to 3.6 V or	4.5 V to 5.5 V		0.40		0.4	V
V _{OL}	voltage L1/L2/L5/L7/L8	$I_{OL} = 2 \text{ mA}, V_{IO} = 1.65 \text{ to } 1.95$					0.4	V
	Positive-going input	$V_{CC} = 3.3 V$				1.6	2.4	V
V _{IT+}	threshold voltage on RS-232 receiver inputs (R1, R2, R5, R7, R8)	V _{CC} = 5 V				1.9	2.4	V
	Negative-going input	V _{CC} = 3.3 V			0.6	1.1		V
V _{IT-}	threshold voltage on RS-232 receiver inputs (R1, R2, R5, R7, R8)	V _{CC} = 5 V			0.8	1.4		v
V _{hys}	Input hysteresis on receiver inputs $(V_{IT+} - V_{IT-})$				0.4	0.5		V
l _{off}	Output leakage current on receiver output pins L1/L2/L5/L7/L8	SHDN = 0 V				±0.05	±10	μA
rı	Input resistance on receiver input pins	-15 V ≤ V _I ≤ 15 V			3	5	7	kΩ
Thermal F	Protection	1						
T _{SHDN}	Thermal shutdown threshold	Temperature rising			150	170		°C
T _{HYS}	Thermal shutdown hysteresis					15		°C
Supply		,						
UV _{VCC} (rising)	Rising under-voltage threshold on V _{CC}					2.5	2.8	V
JV _{VCC} falling)	Falling under-voltage threshold on V _{CC}				1.9	2.1		V
UV _{VCC(hys}	Hysteresis on under-voltage of V_{CC}				100	400		mV
UV _{VIO} (rising)	Rising under-voltage threshold on V _{IO}					1.5	1.6	V
UV _{VIO} (falling)	Falling under-voltage threshold on V _{IO}				1.2	1.4		V
JV _{VIO(hys)}	Hysteresis on under-voltage of V_{IO}				85	100		mV



5.7 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted). All typical values are at 25°C and supply voltage of V_{CC} = 5 V. V_{10} = 3.3 V . unless otherwise noted.

	PARAMETER	TEST CONDITIONS		MIN	ТҮР	MAX	UNIT
		V_{CC} = 4.5 V to 5.5 V, SHDN = GND, All other logic inpload on bus, T _A ≤ 125 °C	out pins floating, no		5	20	μA
	Supply current in shutdown	V_{CC} = 3 V to 3.6 V, \overline{SHDN} = GND, All other logic input on bus, T_A ≤ 125 $^\circ C$	t pins floating, no load		3	15	μA
I _{CC_SHDN}	mode	V_{CC} = 4.5 V to 5.5 V, SHDN = GND, All other logic input pins floating, no load on bus, $T_A \leq 105\ ^\circ C$			5	15	μA
		V_{CC} = 3 V to 3.6 V, \overline{SHDN} = GND, All other logic input on bus, T_A ≤ 105 $^\circ C$	t pins floating, no load		3	10	μA
I _{IO_SHDN}	Logic supply current in shutdown mode	V_{IO} = 1.65 V to 5.5 V, SHDN = GND, All other logic in	put pins floating			2	μA
	Supply current (quiescent),	Driver and receiver enabled, DIR = V _{IO} , MODE2, MODE1, MODE0 = 011 (Full duplex)	No load		1.7	3.4	mA
I _{CC_485}	V _{CC} = 4.5 V to 5.5 V TERM_RX, TERM_TX= Floating or low, SLR = X	Driver enabled, receiver disabled, DIR = V _{IO} , MODE2, MODE1, MODE0 = 010 (Half duplex)	No load		1.3	2.8	mA
	, , , , , , , , , , , , , , , , , , ,	Driver disabled, receiver enabled, DIR = GND, MODE2, MODE1, MODE0 = 010 (Half duplex)	No load		0.8	1.5	mA
	Supply current (quiescent),	Driver and receiver enabled, DIR = V _{IO} , MODE2, MODE1, MODE0 = 011 (Full duplex)	No load		1.5	2.8	mA
I _{CC_485}	V _{CC} = 3 V to 3.6 V TERM_RX, TERM_TX=	Driver enabled, receiver disabled, DIR = V _{IO} , MODE2, MODE1, MODE0 = 010 (Half duplex)	No load		1	2.3	mA
	Floating or low, SLR = X	Driver disabled, receiver enabled, DIR = GND, MODE2, MODE1, MODE0 = 010 (Half duplex)	No load		0.7	1.3	mA
I _{IO 485}	Logic supply current (quiescent), V _{IO} = 3 to 3.6 V	Driver disabled, Receiver enabled, SLR = GND, DIR = GND; MODE2, MODE1, MODE0 = 010 (half duplex)	No load		7	17	μA
	TERM_RX, TERM_TX= Floating	Driver disabled, Receiver enabled, SLR = V _{IO} ; DIR = GND; MODE2, MODE1, MODE0 = 010 (half duplex)	No load		8	21	μA
I _{CCDT_485}	Supply current in RS-485 driver termination mode	Driver enabled with termination ON; MODE2, MODE1, MODE0 = 011 (full duplex)	DIR= V _{IO} , TERM_TX = V _{IO}		38	50	mA
I _{CCRT_485}	Supply current in RS-485 receiver termination mode	Receiver enabled with termination ON; MODE2, MODE1, MODE0 = 011 (full duplex)	DIR = GND, TERM_RX = V _{IO}		1	1.5	mA
I _{CC_RS232}	Supply current in RS-232 mode	MODE2, MODE1, MODE0 = 001, $\overline{SHDN} = V_{IO}$; other logic inputs floating	No load		4	6	mA
I _{CC_RS232} _LB	Supply current in RS-232 loopback mode	$\begin{array}{l} MODE2=x, \ MODE1=0, \ MODE0=0; \ L3=L4=L6\\ = \ static \ logic \ high, \ -40 \ ^\circC \leq T_A \leq 85 \ ^\circC \end{array}$	No extra load on RS-232 drivers or on logic output		25	31	mA
I _{CC_RS485} _LB	Supply current in RS-485 loopback mode	MODE2 = MODE1= MODE0 = V _{IO} ; L3 = static logic high	No load on bus or logic output		3	4	mA
On-Chip to	ermination resistor_RS-485						
R _{TERM_TX}	120 Ω termination across Driver output R1/R2 terminals	MODE2, MODE1, MODE0 = 011 (Full duplex) or 010 GND, TERM_TX = V _{IO} , V _{R2R1} = 2 V, V _{R1} = -7 V, 0 V, 1		102	120	138	Ω
R _{TERM_RX}	120 Ω termination across receiver output R3/R4 terminals	MODE2, MODE1, MODE0 = 011 (Full duplex); TERM V, V _{R4} = -7 V, 0 V, 10 V; See Figure 6-9	_RX = V _{IO} , V _{R3R4} = 2	102	120	138	Ω
Logic	1	1					
I _{IN}	Input current (L3, L4, L6, DIR, SHDN, SLR, TERM_TX, TERM_RX, MODE2, MODE1, MODE0)	$1.65 \text{ V} \leq \text{V}_{\text{IO}} \leq 5.5 \text{ V}, 0 \text{ V} \leq \text{V}_{\text{IN}} \leq \text{V}_{\text{IO}}$		-20		5	μA
V _{IT+(IN)}	Rising threshold: logic inputs				0.6*V _{IO}	0.7*V _{IO}	V
V _{IT-(IN)}	Falling threshold: logic inputs	1.65 V ≤ V _{IO} ≤ 5.5 V		0.3*V _{IO}	0.4*V _{IO}		V
V _{IN(HYS)}	Input threshold: logic inputs	1		0.1*V _{IO}	0.2*V _{IO}		V

(1)

Under any specific conditions, V_{TH+} is assured to be at least V_{HYS} higher than V_{TH-} . Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one (2) output should be shorted at a time.

5.8 Switching Characteristics_RS-485_500kbps

500-kbps (with SLR = V_{IO}) over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V, V_{IO} = 3.3 V, unless otherwise noted. ⁽¹⁾

	PARAMETER	TEST CONDI	TIONS	MIN	TYP	MAX	UNIT
Driver							
	Differential output rise/fall time		V _{CC} = 3 to 3.6 V, Typical at 3.3V	210	300	600	ns
t _r , t _f	Dinerential output rise/fair time		V _{CC} = 4.5 to 5.5 V, Typical at 5 V	250	300	600	ns
	Propagation delay	R _L = 54 Ω, C _L = 50 pF	V _{CC} = 3 to 3.6 V, Typical at 3.3V		250	450	ns
t _{PHL} , t _{PLH}	See Figure 6-3	See Figure 6-3	V _{CC} = 4.5 to 5.5 V, Typical at 5 V		250	450	ns
			V _{CC} = 3 to 3.6 V, Typical at 3.3V		2	15	ns
t _{SK(P)}			V _{CC} = 4.5 to 5.5 V, Typical at 5 V		2	15	ns
t _{PHZ} , t _{PLZ}	Disable time	MODE2, MODE1, MODE0 = 010 (half duplex) or 011 (full duplex)	See Figure 6-4		80	150	ns
t _{PZH} , t _{PZL}	Enable time	MODE2, MODE1, MODE0 = 011 (full duplex): receiver enabled	and Figure 6-5		200	650	ns
Receiver							
t _r , t _f	Output rise/fall time				5	10	ns
t _{PHL} , t _{PLH}	Propagation delay	C _L = 15 pF	See Figure 6-6		700	1200	ns
t _{SK(P)}	Pulse skew, t _{PHL} – t _{PLH}				10	45	ns
t _{PHZ} , t _{PLZ}	Disable time in half duplex mode				30	80	ns
t _{PZH(1)}	Enable time in helf duploy made	MODE2, MODE1, MODE0 = 010, TERM TX = V_{IO}	See Figure 6-7		60	155	ns
t _{PZL(1)}	Enable time in half duplex mode	$r_{1} = r_{10}$			450	1250	ns
t _{PZH(2)} , t _{PZL(2)}	Enable time from shutdown with TX disabled in full duplex mode	DIR = 0 V; MODE2, MODE1, MODE0 = 011	See Figure 6-8		7	16	μs

(1) R3, R4 are RX input, R2/R1 are driver output terminals in Full duplex mode

5.9 Switching Characteristics_RS-485_20Mbps

20-Mbps (SLR = GND) over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V, V_{IO} = 3.3 V. ⁽¹⁾

	PARAMETER	TEST COND	TIONS	MIN	TYP	MAX	UNIT
Driver							
t _r , t _f Diffe	Differential entry trice/fall time		V _{CC} = 3 to 3.6 V, Typical at 3.3 V	5	10	15	ns
	Differential output rise/fall time		V_{CC} = 4.5 to 5.5 V, Typical at 5 V	5	10	15	ns
	Deservation delau	R _L = 54 Ω, C _L = 50 pF	V _{IO} = 1.65 V to 1.95V	14	25	58	ns
t _{PHL} , t _{PLH} Propagation delay	Propagation delay	See Figure 6-3	V _{IO} = 3 V to 3.6 V	9	20	46	ns
1	Pulse skew, t _{PHL} – t _{PLH}		V _{CC} = 3 to 3.6 V, Typical at 3.3 V		1	3.5	ns
t _{SK(P)}			V_{CC} = 4.5 to 5.5 V, Typical at 5 V		1	3.5	ns
t _{PHZ} , t _{PLZ}	Disable time	MODE2, MODE1, MODE0 = 010 (half duplex) or 011 (full duplex)	See Figure 6-4		11	65	ns
t _{PZH} , t _{PZL}	Enable time	MODE2, MODE1, MODE0 = 011 (full duplex): receiver enabled	and Figure 6-5		8	80	ns
Receiver							



5.9 Switching Characteristics RS-485 20Mbps (continued)

20-Mbps (SLR = GND) over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 $V_{10} = 3.3 V_{.}$ (1)

• , • ₁₀ •							
	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
t _r , t _f	Output rise/fall time				5	10	ns
t _{PHL} , t _{PLH}	Propagation delay	C _L = 15 pF	See Figure 6-6		40	70	ns
t _{SK(P)}	Pulse skew, t _{PHL} – t _{PLH}					10	ns
t _{PHZ} , t _{PLZ}	Disable time in half duplex mode				20	80	ns
t _{PZH(1)} , t _{PZL(1)}	Enable time in half duplex mode (includes driver disable time as per setup)	MODE2, MODE1, MODE0 = 010, TERM_TX = V _{IO}	See Figure 6-7		50	160	ns
t _{PZH(2)} , t _{PZL(2)}	Enable time from shutdown with TX disabled in full duplex mode	DIR = 0 V; MODE2, MODE1, MODE0 = 011	See Figure 6-8		4	15	μs

(1) R3, R4 are RX input, R2/R1 are driver output terminals in Full duplex mode.

5.10 Switching Characteristics, Driver_RS232

over recommended ranges of supply voltage and operating free-air temperature(unless otherwise noted)⁽¹⁾

	PARAMETER		ONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
250 kbp)S						
	Maximum data rate	$R_L = 3 k\Omega$ One DOUT switching	C _L = 2500 pF See Figure 6-16	250	500		kbps
t _{PHL} , t _{PHL}	Transmitter propagation delay	R_L = 3 kΩ to 7 kΩ	$C_{L} = 150 \text{ pF to } 2500 \text{ pF}$		0.8	2	μs
t _{sk(p)}	Transmitter Pulse skew ⁽³⁾		See Figure 6-16		220	600	ns
	a	$V_{CC} = 3.3 V \pm 10\%, 5 V \pm 10\%,$	C _L = 150 pF to 1000 pF	6		30	
SR(tr)	Slew rate, transition region	$R_L = 3 k\Omega$ to 7 kΩ, See Figure 6-17	C _L = 150 pF to 2500 pF	4		30	V/µs
1 Mbps							
		$R_L = 3 k\Omega$	C_L = 250 pF, V_{CC} = 3 to 3.6 V	1000			kbps
	Maximum data rate	One DOUT switching,See Figure 6-16	C_{L} = 1000 pF, V_{CC} = 4.5 to 5.5 V	1000			kbps
t _{PLH} , t _{PHL}	Transmitter propagation delay	R_L = 3k to 7 k Ω , See Figure 6-16	C _L = 150 pF to 1000 pF		300	800	ns
t _{sk(p)}	Pulse skew ⁽³⁾				25	150	ns
$R_{L} = 3k \text{ to } 7 \text{ k}\Omega, V_{CC} = 4.5 \text{V to}$ 5.5V $C_{1} = 150 \text{ pF to } 100$	C _L = 150 pF to 1000 pF	18		150	V/µs		
SR(tr)	Slew rate, transition region	R_L = 3k to 7 k Ω , V_{CC} = 3V to 3.6V	See Figure 6-17	15		150	V/µs

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V + 0.3 V; V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device. (1)

(2)

(3)

5.11 Switching Characteristics, Receiver_RS232

over recommended ranges of supply voltage and operating free-air temperature (unlessotherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
250 kbp	S					
t _{PLH}	Propagation delay time, low- to high-level output	C ₁ = 150 pF, See Figure 6-18		150	550	ns
t _{PHL}	Propagation delay time, high- to low-level output			150	550	ns
t _{PLH}	Propagation delay time, low- to high-level output	C ₁ = 15 pF, See Figure 6-18		130	520	ns
t _{PHL}	Propagation delay time, high- to low-level output			130	520	ns
	Rise/fall time (receiver buffer output), V_{10} = 3 to 5.5 V	C _L = 150 pF, See Figure 6-18		20	50	ns
t _{R 232} ,	Rise/fail time (receiver buller output), $v_{IO} = 3.003.5$ v	C _L = 15 pF, See Figure 6-18		5	10	ns
t _{R_232} , t _{F_232}	Rise/fall time (receiver buffer output), V_{IO} = 1.65 to	C _L = 150 pF, See Figure 6-18		40	90	ns
	2.75 V	C _L = 15 pF, See Figure 6-18		10	20	ns

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5.11 Switching Characteristics, Receiver RS232 (continued)

over recommended ranges of supply voltage and operating free-air temperature (unlessotherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN TYP ⁽²⁾	MAX	UNIT
t _{en}	Output enable time	$C_{1} = 150 \text{ m} \Gamma_{1} \Gamma_{2} = 2400 \text{ Sec. Figure 6.10}$	6	14	us
t _{dis}	Output disable time	$-C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega$, See Figure 6-19	100	200	ns
	Dulas alveu(3)	C _L = 150 pF, See Figure 6-18	50	135	ns
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 15 pF, See Figure 6-18	50	135	ns
1 Mbps					
t _{PLH}	Propagation delay time, low- to high-level output		150	550	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 6-18	150	550	ns
t _{PLH}	Propagation delay time, low- to high-level output		130	520	ns
t _{PHL}	Propagation delay time, high- to low-level output	- C _L = 15 pF, See Figure 6-18	130	520	ns
	Disc (fall time (receiver b) (for output)) $(-2 to 5.5)$	C _L = 150 pF, See Figure 6-18	20	50	ns
t _{R_232} ,	Rise/fall time (receiver buffer output), V_{IO} = 3 to 5.5 V	C _L = 15 pF, See Figure 6-18	5	10	ns
t _{F_232}	Rise/fall time (receiver buffer output), V_{IQ} = 1.65 to	C _L = 150 pF, See Figure 6-18	40	90	ns
	2.75 V	C _L = 15 pF, See Figure 6-18	10	20	ns
t _{en}	Output enable time		6	14	us
t _{dis}	Output disable time	$-C_{L} = 150 \text{ pF}, R_{L} = 3 \text{ k}\Omega$, See Figure 6-19	100	200	ns
	Dulas skew(3)	C _L = 150 pF, See Figure 6-18	50	125	ns
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 15 pF, See Figure 6-18	50	125	ns

Test conditions are C1–C4 = 0.1 μ F atV_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F atV_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V orV_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device. (1)

(2)

(3)

5.12 Switching Characteristics_MODE switching

Parameters over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V , V_{IO} = 3.3 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
+	Time from Shutdown to RS-232	MODE2, MODE1, MODE0 = 000 or floating; \overline{SHDN} = GND to V _{IO} ; rest of logic input pins floating, V _{CC} = 4.5 V to 5.5 V Time from 50% of rising SHDN to charge pump V- supply reaching -8 V; See Figure 6-11		0.05	0.1	ms
t _{RDY}	ready	MODE2, MODE1, MODE0 = 000 or floating; SHDN = GND to V_{10} ; rest of logic input pins floating, V_{CC} = 3 V to 3.6 V Time from 50% of rising SHDN to charge pump V- supply reaching -5 V; See Figure 6-11		0.1	0.4	ms
t _{R2_R4}	Time to switch from RS-232 3T5R mode to RS-485 Full duplex mode	$ \begin{array}{l} \text{L3 = Vio, MODE2 = GND, MODE1 from GND to Vio, MODE0} \\ \text{= Vio; } \overline{\text{SHDN}} = \text{DIR} = \text{V}_{\text{IO};} \text{ SLR, TERM_TX, TERM_RX=} \\ \text{floating; Time from 50\% of MODE1 rising edge to R2 reaching} \\ \text{2V; See Figure 6-12} \end{array} $		0.04	0.1	μs
t _{R4_R2}	Time to switch from RS-485 full dupplex mode to RS-232 3T5R mode	L3 = Vio, MODE2 = GND, MODE1 from Vio to GND, MODE0 = Vio; SHDN = DIR = V_{IO} ; SLR, TERM_TX, TERM_RX= floating; Time from 50% of MODE1 falling edge to R2 reaching 300 mV; See Figure 6-12		2	2.1	μs
t _{LP_RS232}	Time to switch from RS-232 loopback mode to normal RS-232 mode	$\begin{array}{l} \mbox{MODE2} = \mbox{MODE1} = \mbox{GND} \ \mbox{form} \ \mbox{GND} \ \mbox{to} \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$		2	2.4	μs
t _{RS232_LP}	Time to switch from normal RS-232 mode to RS-232 loopback mode	$\begin{array}{l} \mbox{MODE2} = \mbox{MODE1} = \mbox{GND}, \mbox{MODE0} \mbox{ from } V_{IO} \mbox{ to GND}; \end{tabular} \mbox{SHDN} = \\ V_{IO}, \mbox{L3} = \mbox{GND}; \end{tabular} \mbox{Time from } 50\% \mbox{ of MODE0} \mbox{ falling edge to L2} \\ \mbox{50\% falling edge, } -40 \end{tabular} \mbox{C} \leq T_A \leq 85 \end{tabular} \mbox{C}; \end{tabular} \mbox{Sec} \mbox{Figure 6-13} \end{array}$		2	15	μs
t _{LP_RS485}	Time to switch from RS-485 loopback mode to RS-485 full duplex mode	$\begin{array}{l} \text{MODE1} = \text{MODE0} = \text{V}_{\text{IO}}; \text{MODE2} \text{ from } \text{V}_{\text{IO}} \text{ to GND}; \overline{\text{SHDN}} \\ = \text{V}_{\text{IO}}, \text{ SLR}, \text{TERM}_{\text{TX}}, \text{TERM}_{\text{RX}} = \text{floating}; \text{L3} = \text{GND}, \\ \text{Time from 50\% of MODE2} \text{ falling edge to 50\% of rising L2}; \\ \text{See Figure 6-14} \end{array}$		40	50	μs
t _{RS485_LP}	Time to switch from RS-485 full duplex mode to RS-485 loopback mode	$\begin{array}{l} \text{MODE1} = \text{MODE0} = V_{\text{IO}}; \text{MODE2} \text{ from GND to } V_{\text{IO}}; \overline{\text{SHDN}} \\ = V_{\text{IO}}, \text{ SLR}, \text{TERM}_{\text{TX}}, \text{TERM}_{\text{RX}} = \text{floating}; \text{L3} = \text{GND}, \\ \text{Time from 50\% of MODE2} \text{ rising edge to 50\% of falling} \\ \text{L2}; \text{ See Figure 6-14} \end{array}$		1	2	μs



5.12 Switching Characteristics_MODE switching (continued)

Parameters over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V , V_{IO} = 3.3 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{FHD_RS485}	Time to switch from RS-485 full duplex to half duplex mode	$\begin{array}{l} \text{DIR=V}_{\text{IO}}, \text{MODE2} = \text{GND}, \text{MODE1} = \text{V}_{\text{IO}}; \text{MODE0} \text{ from V}_{\text{IO}} \\ \text{to GND} ; \overline{\text{SHDN}} = \text{V}_{\text{IO}}, \text{SLR}, \text{TERM}_{\text{TX}}, \text{TERM}_{\text{RX}} = \text{floating}; \\ \text{L3} = \text{GND}, 10\text{k pull down resistor on L2}, \text{Time from 50\% of} \\ \text{MODE0} \text{ falling edge to 50\% falling edge on L2}; \text{See Figure} \\ \text{6-15} \end{array}$		0.5	1	μs
t _{HFD_RS485}	Time to switch from RS-485 half duplex to full duplex mode	$\begin{array}{l} \text{DIR=V}_{\text{IO}}, \text{MODE2} = \text{GND}, \text{MODE1} = \text{V}_{\text{IO}}; \text{MODE0} \text{ from GND} \\ \text{to } \text{V}_{\text{IO}}; \overline{\text{SHDN}} = \text{V}_{\text{IO}}, \text{SLR}, \text{TERM}_{\text{TX}}, \text{TERM}_{\text{RX}} = \text{floating}; \\ \text{L3} = \text{GND}, 10\text{k pull down resistor on L2}, \text{Time from 50\% of} \\ \text{MODE0} \text{ rising edge to 50\% rising edge on L2}; \text{See Figure} \\ \text{6-15} \end{array}$		0.5	1	μs

5.13 Switching Characteristics_RS-485_Termination resistor

Parameters over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V , V_{IO} = 3.3 V, unless otherwise noted.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{DTEN}	Driver terminal Termination resistor turn-on time	$\begin{array}{l} \mbox{MODE2, MODE1, MODE0 = 011; V_{IO} = 3 to 3.6 V, DIR = $$$$ GND, V_{R2R1} = 2 V, V_{R1} = 0 V; See Figure 6-10 $$ \end{array}$		1000	2200	ns
t _{DTZ}	Driver terminal Termination resistor turn-off time	MODE2, MODE1, MODE0 = 011; V_{IO} = 3 to 3.6 V, DIR = GND, V_{R2R1} = 2 V, V_{R1} = 0 V; See Figure 6-10		2000	7200	ns
t _{RTEN}	Receiver terminal Termination resistor turn-on time	MODE2, MODE1, MODE0 = 011; V_{IO} = 3 to 3.6 V, V_{R3R4} = 2 V, V_{R4} = 0 V; See Figure 6-10		1000	2200	ns
t _{RTZ}	Receiver terminal Termination resistor turn-off time	MODE2, MODE1, MODE0 = 011; V _{IO} = 3 to 3.6 V, V _{R3R4} = 2 V, V _{R4} = 0 V; See Figure 6-10		2000	7200	ns

5.14 Switching Characteristics_Loopback mode

Parameters over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V , V_{IO} = 3.3 V, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{LB RS232 ris}	Delay from Logic input rising edge to logic output rising edge	$\begin{array}{l} \mbox{MODE2}=X,\mbox{ MODE1},\mbox{ MODE0}=\mbox{GND};\mbox{ SLR}=\mbox{GND},\mbox{Delay} \\ \mbox{from 50\% of } L3/L4/L6 \mbox{ rising edge to 50\% } L2/L1/L5,\mbox{ L7},\mbox{ L8} \\ \mbox{rising edge, } \overline{\mbox{SHDN}}=\mbox{Vio, TERM}_TX \mbox{ and TERM}_RX \mbox{ float}, \\ \mbox{Load capacitance on output buffers}=15 \mbox{ pF},\mbox{ R}_L \mbox{ on all 3 driver} \\ \mbox{outputs}=3k\Omega,\mbox{ -40 °C} \leq T_A \leq 85 \mbox{ °C} \end{array}$		410	920	ns
ing	in RS-232 Loopback mode	$\begin{array}{l} \mbox{MODE2}=X,\mbox{ MODE1},\mbox{ MODE0}=\mbox{GND};\mbox{ SLR}=\mbox{Vio},\mbox{ Delay from} \\ 50\%\mbox{ of }L3/L4/L6\mbox{ rising edge to }50\%\mbox{ L2/L1/L5},\mbox{ L7},\mbox{ L8}\mbox{ rising} \\ \mbox{ edge},\mbox{ SHDN}=\mbox{Vio},\mbox{ TERM}_TX\mbox{ and TERM}_RX\mbox{ float},\mbox{ Load} \\ \mbox{ capacitance on output buffers}=15\mbox{ pF},\mbox{ R}_L\mbox{ on all 3 driver} \\ \mbox{ outputs}=3k\Omega,\mbox{ -40 }^\circ C\leq T_A\leq 85 ^\circ C \end{array}$		640	1100	ns
t _{LB_RS232_fal} edge to	Delay from Logic input falling edge to logic output falling edge in RS-232 Loopback mode	$\begin{array}{l} \text{MODE2}=\text{X}, \text{MODE1}, \text{MODE0}=\text{GND}; \text{SLR}=\text{GND}, \text{Delay} \\ \text{from 50\% of L3/L4/L6 falling edge to 50\% L2/L1/L5, L7,} \\ \text{L8 falling edge}, \overline{\text{SHDN}}=\text{Vio, TERM_TX and TERM_RX} \\ \text{float, Load capacitance on output buffers}=15 \text{ pF, } \text{R}_{\text{L}} \text{ on all} \\ \text{3 driver outputs}=3\text{k}\Omega, -40\ ^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 85\ ^{\circ}\text{C} \end{array}$		570	760	ns
		$\begin{array}{l} \mbox{MODE2}=X,\mbox{ MODE1},\mbox{ MODE0}=\mbox{GND};\mbox{ SLR}=\mbox{Vio},\mbox{ Delay from} \\ 50\%\mbox{ of L3/L4/L6 falling edge to } 50\%\mbox{ L2/L1/L5},\mbox{ L7},\mbox{ L8} falling \\ \mbox{edge},\mbox{ SHDN}=\mbox{Vio},\mbox{ TERM}_TX\mbox{ and TERM}_RX\mbox{ float},\mbox{ Load} \\ \mbox{ capacitance on output buffers}=15\mbox{ pF},\mbox{ R}_L\mbox{ on all 3 driver} \\ \mbox{ outputs}=3k\Omega,\mbox{ -40 °C}\leq T_A\leq85\mbox{ °C} \end{array}$		600	1460	ns
t _{SKEW_RS23}	Pulse skew from logic input to	t_LB_RS232_rising - t_LB_RS232_failing , SLR = Vio, -40 $^\circ C \leq T_A \leq 85 ^\circ C$		100	860	ns
2_LB	logic output in RS232 loopback mode	$ t_{LB_RS232_rising} - t_{LB_RS232_falling} , SLR = GND, -40 \text{ °C} \le T_A \le 85 \text{ °C} $	70 25	250	ns	
t _{LB_RS485_} ris ing	Delay from Logic input rising edge to logic output rising edge in RS-485 Loopback mode	$\begin{array}{l} \mbox{MODE2} = \mbox{MODE1} = \mbox{MODE0} = \mbox{Vio}; \mbox{SLR} = \mbox{Vio}, \mbox{Delay from} \\ \mbox{50\% of L3 rising edge to 50\% L2 rising edge, } \mbox{SHDN} = \mbox{Vio}, \\ \mbox{TERM_TX and TERM_RX float, Load cap on L2 = 15 pF, Load} \\ \mbox{on Driver output terminals} (R2-R1) = 54 \ \Omega \end{array}$		1060	1770	ns



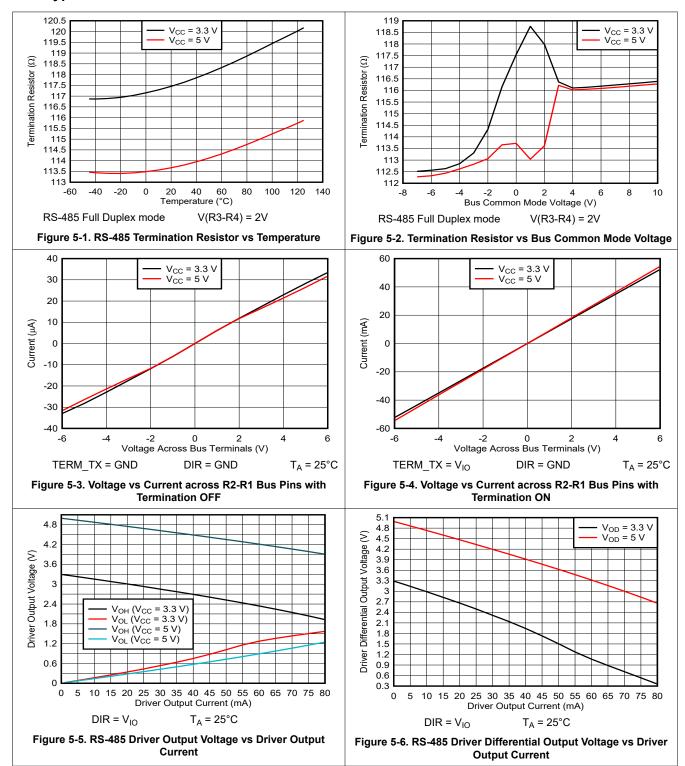
5.14 Switching Characteristics_Loopback mode (continued)

Parameters over recommended operating conditions. All typical values are at 25°C and supply voltage of V_{CC} = 5 V , V_{IO} = 3.3 V, unless otherwise noted.

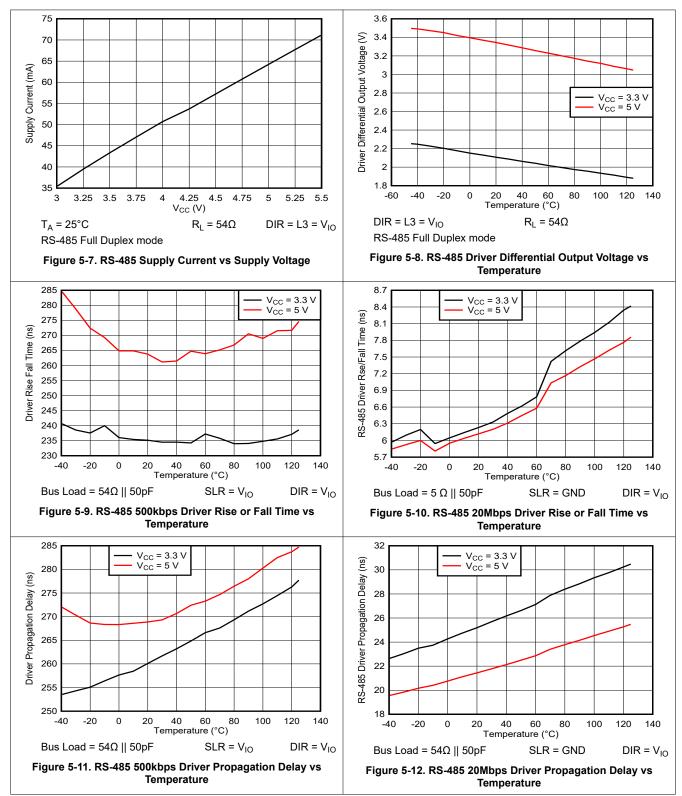
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{LB_RS485_fal} ling	Delay from Logic input falling edge to logic output falling edge in RS-485 Loopback mode	$\begin{array}{l} \text{MODE2} = \text{MODE1} = \text{MODE0} = \text{Vio}; \ \text{SLR} = \text{Vio}, \ \text{Delay from} \\ \text{50\% of L3 falling edge to 50\% L2 falling edge, } \\ \text{FRM_TX and TERM_RX float, Load cap on L2} = 15 \ \text{pF, Load} \\ \text{on Driver output terminals (R2-R1)} = 54 \ \Omega \end{array}$		1060	1770	ns
t _{SKEW_RS48} 5_LB	Pulse skew from logic input to logic output in RS485 loopback mode	$ t_{LB_RS485_rising} - t_{LB_RS485_falling} $, SLR = Vio		5	50	ns



5.15 Typical Characteristics

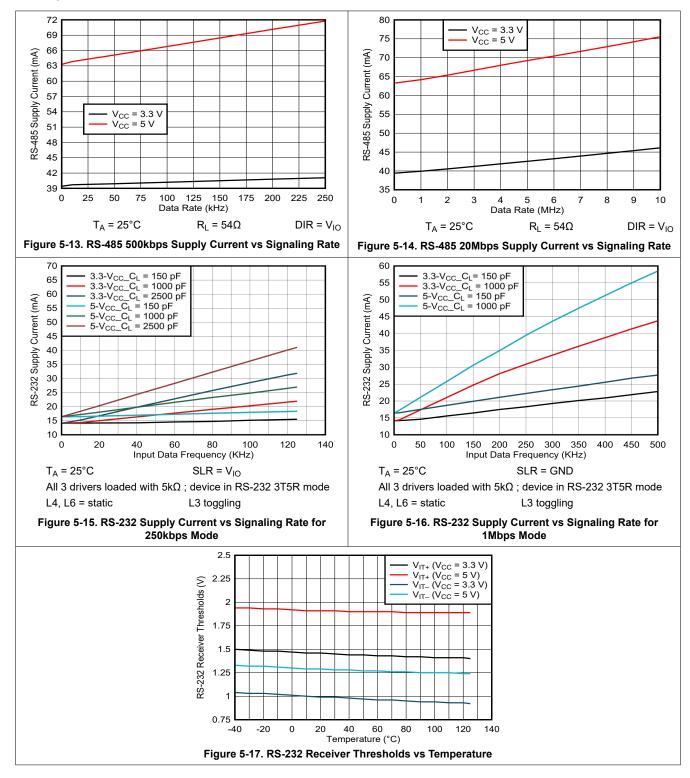


5.15 Typical Characteristics (continued)





5.15 Typical Characteristics (continued)



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6 Parameter Measurement Information

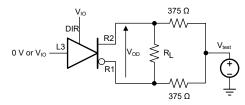


Figure 6-1. Measurement of RS-485 Driver Differential Output Voltage With Common-Mode Load

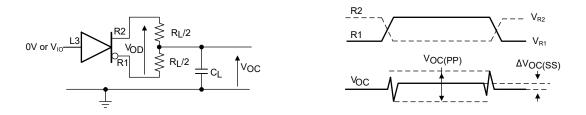


Figure 6-2. Measurement of RS-485 Driver Differential and Common-Mode Output With RS-485 Load

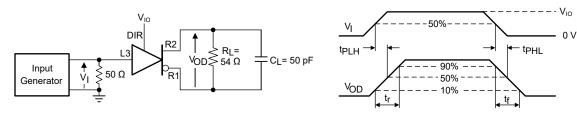


Figure 6-3. Measurement of RS-485 Driver Differential Output Rise and Fall Times and Propagation Delays

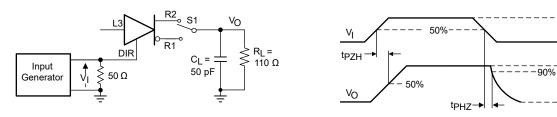


Figure 6-4. Measurement of RS-485 Driver Enable and Disable Times With Active High Output and **Pull-Down Load**

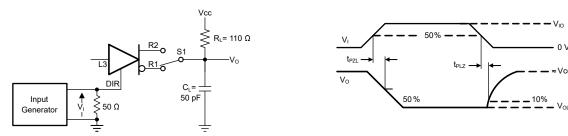


Figure 6-5. Measurement of RS-485 Driver Enable and Disable Times With Active Low Output and Pull-up Load

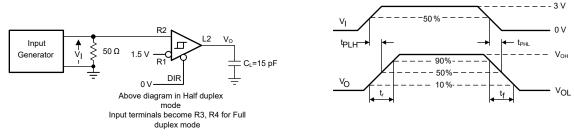


Figure 6-6. Measurement of RS-485 Receiver Output Rise and Fall Times and Propagation Delays

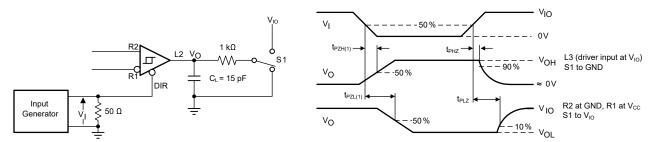


Figure 6-7. Measurement of RS-485 Receiver Enable and Disable Times in Half Duplex Mode

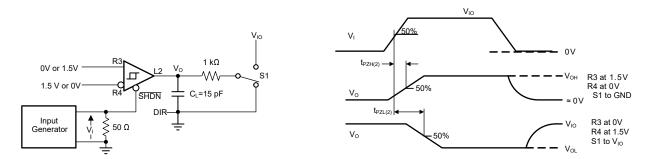


Figure 6-8. Measurement of RS-485 Receiver Enable Time from Shutdown with TX Disabled: Full Duplex Mode



Figure 6-9. Termination Resistor Measurement



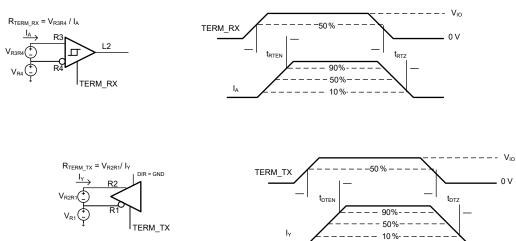


Figure 6-10. Termination Resistor Switching Measurement

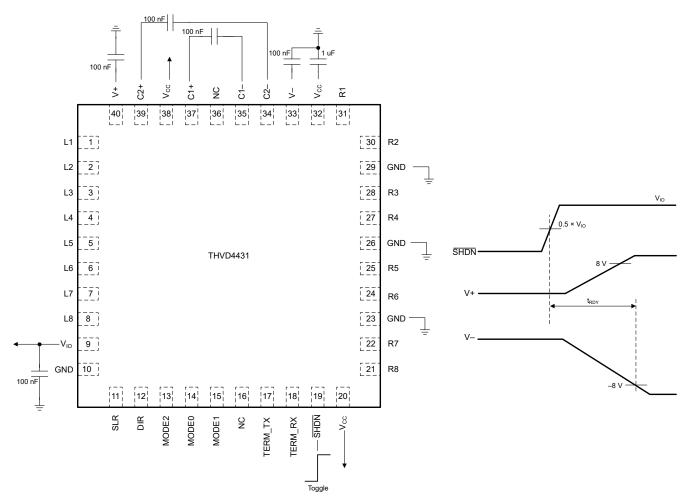


Figure 6-11. Time from Shutdown to RS-232 Ready



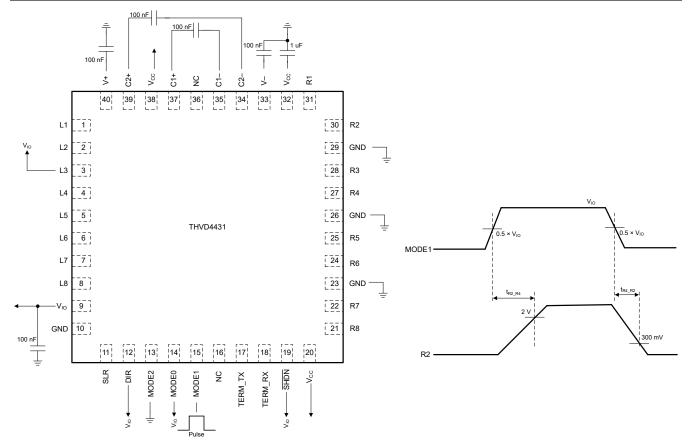


Figure 6-12. Time to Switch from RS-232 3T5R Mode to RS-485 Full Duplex Mode and Back

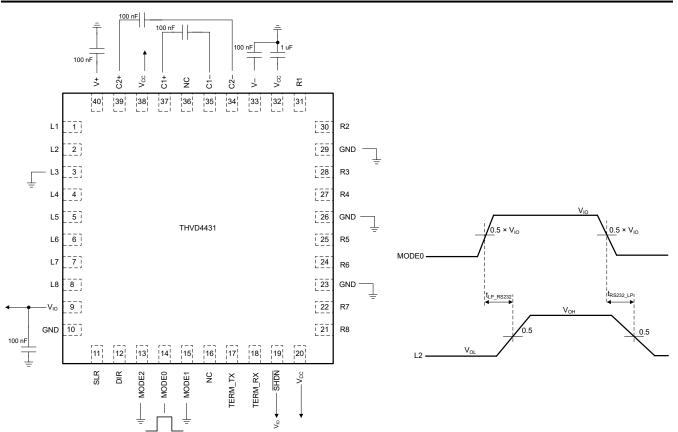


Figure 6-13. Time to Switch from RS-232 Loopback to Normal RS-232 3T5R Mode and Back

Texas

INSTRUMENTS

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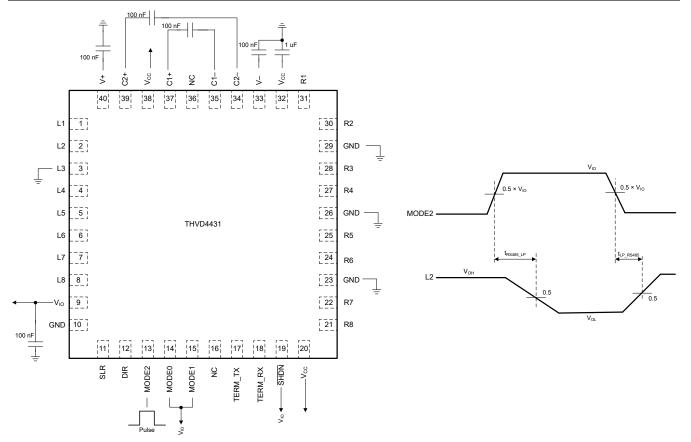
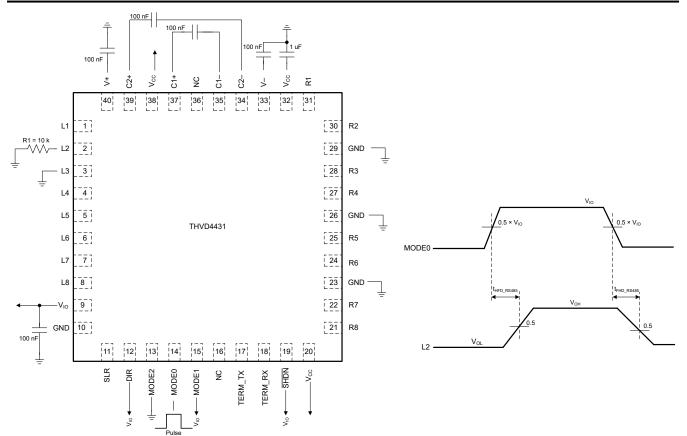
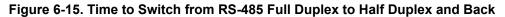


Figure 6-14. Time to Switch from RS-485 Loopback Mode to RS-485 Full Duplex Mode and Back





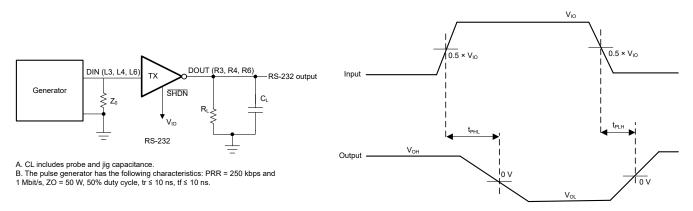


Figure 6-16. RS-232 Driver Prop Delay, Pulse Skew

Texas

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–3 V

90%

10%

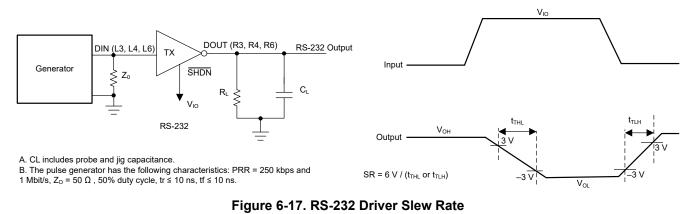
t_{R_232}

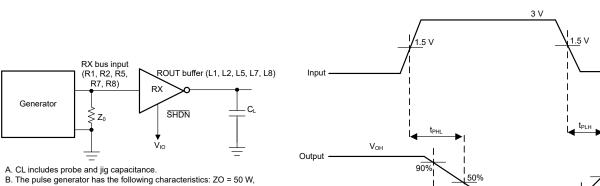
Vol

10%

t_{F_232}

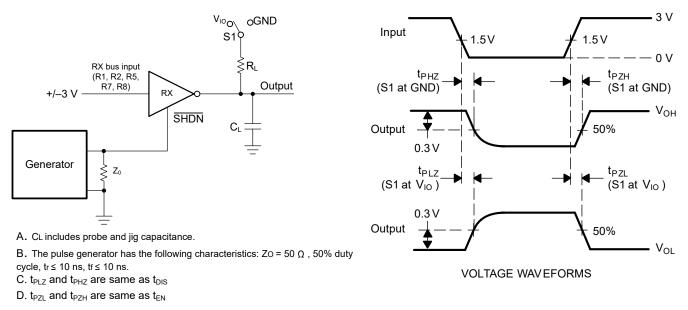
1





B. The pulse generator has the following characteristics: ZO = 50 W, 50% duty cycle, tr \leq 10 ns, tf \leq 10 ns.









7 Detailed Description

7.1 Overview

THVD4431 is a highly integrated and robust multiprotocol transceiver supporting RS-232, RS-422 and RS-485 physical layers. The device has three transmitters and five receivers to enable 3T5R RS-232 port. Device also integrates one transmitter and one receiver to enable half and full duplex RS-485 port. MODE selection pins enable shared bus and logic pins for the protocols to share a common single connector.

The device has SLR pin which allows it to be used for two different maximum speed settings for RS-232 and for RS-485. This is beneficial as customers can qualify one device and use it in two separate end-applications. The devices also have flexible I/O supply pin V_{IO} which enables digital interface voltage range, from 1.65V to 5.5V, different from bus voltage supply 3V to 5.5V.

7.2 Functional Block Diagrams

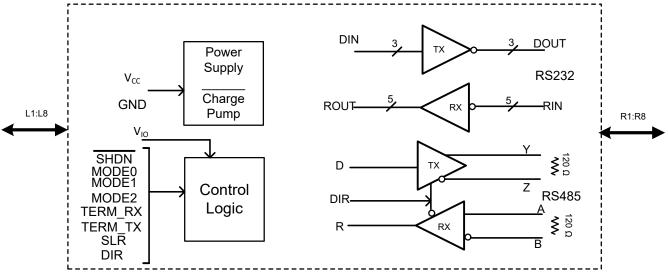


Figure 7-1. THVD4431 Block Diagram

7.3 Feature Description

7.3.1 Integrated IEC ESD and EFT Protection

Internal ESD protection circuits protect all the transceiver bus pins (driver and receiver) against electrostatic discharges (ESD) according to IEC 61000-4-2 up to ±8 kV for contact discharge and ±15 kV for air discharge for all operating modes. Bus lines in RS-485 mode can also withstand electrical fast transients (EFT) according to IEC 61000-4-4 for up to ±4 kV.

7.3.2 Protection Features

The THVD4431 bus pins are protected against any DC supply shorts in the range of -16 V to +16 V. In the RS-485 mode, the short circuit current is limited to ± 250 mA to comply with the TIA/EIA-485A standard. In RS-232 mode, current limiting of ± 60 mA is applicable for scenarios where bus pins can short to ground.

The device also features thermal shutdown protection that disables the driver and the receiver if the junction temperature exceeds the T_{SHDN} threshold due to excessive power dissipation on-chip.

Supply undervoltage protection is present on both V_{CC} and V_{IO} supplies. This maintains the bus output and receiver logic output in known driven state when both the supplies are above their rising undervoltage thresholds. Table below describes the device behavior in various scenarios of supply levels.



V _{cc}	V _{IO}	Driver Output	Receiver Output		
> UV _{VCC(rising)}	> UV _{VIO(rising)}		For RS-485 mode, determined by DIR and (R1-R2) or (R3- R4) inputs. For RS-232 mode, determined by R1, R2, R5, R7, R8 inputs. For shutdown mode, Hi-Z		
< UV _{VCC(falling)}	> UV _{VIO(rising)}	High impedance	Undetermined		
> UV _{VCC(rising)}	< UV _{VIO(falling)}	High impedance	High impedance		
< UV _{VCC(falling)}	< UV _{VIO(falling)}	High impedance	High impedance		

Table 7-1. Supply Function Table

7.3.3 RS-485 Receiver Fail-Safe Operation

The RS-485 differential receiver of the THVD4431 is *failsafe* to invalid bus states caused by the following:

- · Open bus conditions, such as a disconnected connector
- · Shorted bus conditions, such as cable damage shorting the twisted-pair together
- Idle bus conditions that occur when no driver on the bus is actively driving

In any of these cases, the differential receiver outputs a failsafe logic high state so that the output of the receiver is not indeterminate.

Receiver failsafe is accomplished by offsetting the receiver thresholds such that the *input indeterminate* range does not include zero volts differential. To comply with the RS-422 and RS-485 standards, the receiver output must output a high when the differential input V_{ID} is more positive than 200 mV, and must output a low when V_{ID} is more negative than -200 mV. The receiver parameters which determine the failsafe performance are V_{TH+} , V_{TH-} , and V_{HYS} (the separation between V_{TH+} and V_{TH-}). As shown in the *Receiver Function table*, differential signals more negative than -200 mV always causes a low receiver output, and differential signals more positive than 200 mV always causes a high receiver output.

When the differential input signal is close to zero, it is still above the V_{TH+} threshold, and the receiver output is high. Only when the differential input is more than V_{HYS} below V_{TH+} does the receiver output transition to a low state. Therefore, the noise immunity of the receiver inputs during a bus fault conditions includes the receiver hysteresis value, V_{HYS} , as well as the value of V_{TH+} .

7.3.4 Low-Power Shutdown Mode

Driving the SHDN pin low puts the device into the shutdown mode. This is the lowest power mode of the device and current consumption is 10 uA typical. All the blocks get disabled in this mode.

7.3.5 On-chip Switchable Termination Resistor

THVD4431 has 2 termination resistors of nominal 120 Ω , one across R1/R2 and another across R3/R4 in RS-485 mode. Both termination resistors are enabled or disabled using pins as described in Table 7-2. Both the termination resistors can be enabled or disabled independent of the state of driver or receiver. Termination is OFF in RS-232 loopback, RS-232 3T5R, RS-485 loopback, unpowered and thermal shutdown modes.

Signal state	Device mode	Function	Comments
TERM_TX = V _{IO}	Full duplex mode	120 Ω enabled between R1 and R2	Termination between R1/R2 is
TERM_TX = GND or floating	Full duplex mode	120 Ω disabled between R1 and R2	disabled by default
TERM_RX = V _{IO}	Full duplex mode	120 Ω enabled between R3 and R4	Termination between R3/R4 is
TERM_RX = GND or floating	Full duplex mode	120 Ω disabled between R3 and R4	disabled by default
TERM_RX = X, TERM_TX = V _{IO}	Half duplex mode	120 Ω enabled between R1 and R2	In half duplex mode, TERM_RX
TERM_RX = X, TERM_TX = GND	Half duplex mode	120 Ω disabled between R1 and R2	is don't care and TERM_TX has higher priority

Table 7-2. On-chip Termination Function

The on-chip 120 Ω termination resistor is designed for minimum variation across temperature and across common mode voltage on bus pins. The termination block offers a resistive load to the bus, and does not alter the magnitude or phase of the bus signals from DC to 20Mbps signaling. See the typical characteristic curves for variation of termination resistor with voltage and temperature.

7.3.6 Operational Data Rate

THVD4431 can be used in slow speed or fast speed RS-485 and RS-232 applications by configuring Slew rate control (SLR) pin. Table 7-3 describes slew rate control function.

Signal state	Driver	Receiver	Comment
SLR = V _{IO}	Maximum speed of operation for RS-485 = 500kbps. Maximum speed of operation in RS-232 mode is 250kbps	Maximum speed of operation for RS-485 = 500kbps. Maximum speed of operation in RS-232 mode is 250kbps	Active high slew rate limiting applied on driver output. In this configuration, glitch filter in receiver path for RS-485 is enabled
SLR = GND or floating	Maximum speed of operation for RS-485= 20Mbps. Maximum speed of operation in RS-232 mode is 1Mbps	Maximum speed of operation for RS-485 = 20Mbps. Maximum speed of operation in RS-232 mode is 1Mbps	Slew rate limiting on driver output disabled.

Table 7-3. Slew Rate Control Function

For RS-485 half and full duplex modes, receiver path in the slow speed mode (500 kbps) provides additional noise filtering. To attenuate high frequency noise pulses from the bus which can be wrongly interpreted as valid data, SLR = V_{IO} enables a low pass filter to filter out pulses with frequency higher than typical 700 kHz.

7.3.7 Diagnostic Loopback

THVD4431 provides complete path diagnostic loopback modes for both RS-232 and RS-485. These modes internally short bus outputs to bus inputs. So, if data is toggled from logic input, data reaches bus and is reflected back on logic buffer output. This enables MCU to detect bus side short (due to connector/cable) by comparing logic input and logic output.

In RS-232 loopback mode, L3 reflects on L2/R2/R3; L4 reflects on L1/R4/R1; L6 reflects on L5, L7, L8, R5, R6, R7 and R8 enabling to detect short to ground on all bus pins from R1 through R8. RS-232 loopback mode is optimized for -40°C to 85°C ambient temperature. RS-232 diagnostic loopback can be performed on a node (DUT1) even with another node (DUT2) connected via cable, but listening node (DUT2) is not allowed to transmit anything on the RS232 lines while loopback check by DUT1 is ongoing.

In RS-485 loopback mode, internally R2 gets connected to R3 and R1 gets connected to R4. L3 input data is routed to driver output terminals and receiver input terminals and reflects on L2. DIR and TERM_RX are



not supported in this mode. Specific to this mode, external termination on R3/R4 is not supported, but R1/R2 can have internal or external termination. This is able to detect short between R1/R2 and between R3/R4 bus terminals. Recommended maximum data rate for RS-485 diagnostic loopback to detect cable or connector shorts is 500kbps with SLR = V_{IO} .

7.3.8 Integrated Charge pump for RS-232

THVD4431 has integrated high-efficiency and low-noise charge pump to generate large output voltages for RS-232 signals. Charge pump consists of a voltage doubler and an inverter to regulate the voltage to nominal \pm 5.5 V or to \pm 9.5 V for 3.3 V or 5-V V_{CC} operation respectively. Charge pump needs four external ceramic capacitors (2 flying capacitors and 2 storage capacitors) and allows for single supply operation for RS-232. For a generic description of RS-232 charge pump operation, please refer to the blog: How the RS-232 transceiver's regulated charge-pump circuitry works.

7.4 Device Functional Modes

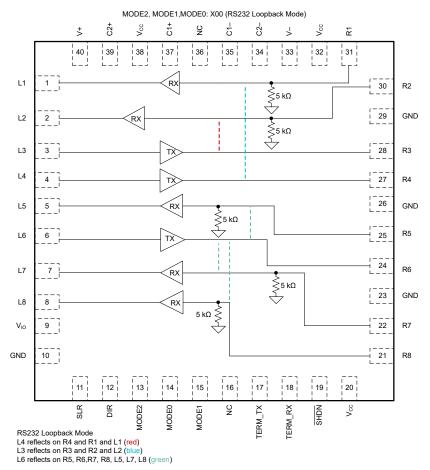
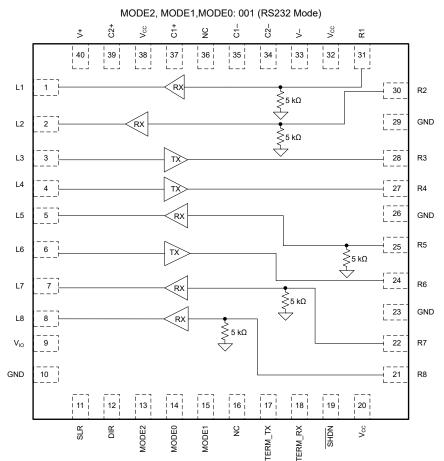
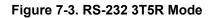
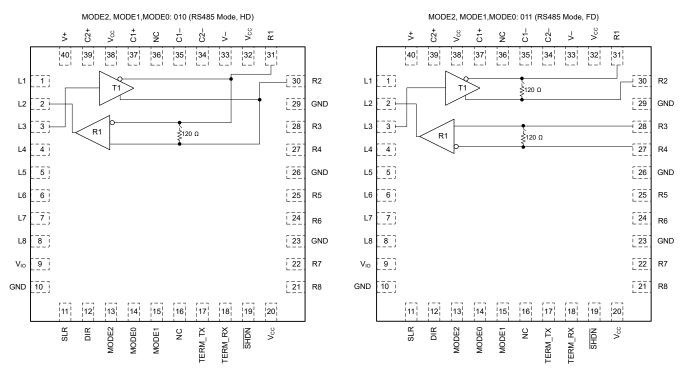


Figure 7-2. RS-232 Loopback Mode













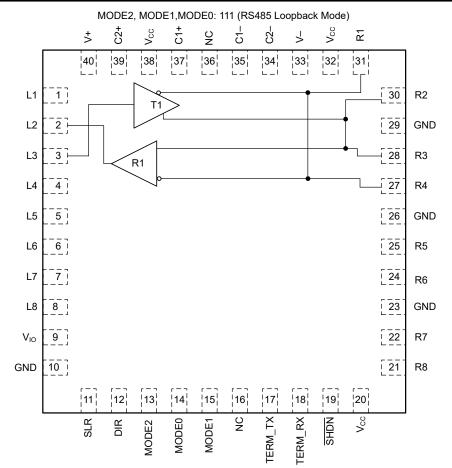


Figure 7-5. RS-485 Loopback Mode



7.4.1 RS-485 Functionality

When the driver enable pin, DIR, is logic high, the differential outputs R2 and R1 follow the logic states at data input L3. A logic high at L3 causes R2 to turn high and R1 to turn low. In this case, the differential output voltage defined as $V_{OD} = V_{R2} - V_{R1}$ is positive. When L3 is low, the output states reverse: R1 turns high, R2 becomes low, and V_{OD} is negative.

When DIR is low, both outputs turn high-impedance. In this condition, the logic state at L3 is irrelevant. The DIR pin has an internal pull-down resistor to ground, thus when left open the driver is disabled (high-impedance) by default. The L3 pin has an internal pull-up resistor to V_{IO} , thus, when left open while the driver is enabled, output R2 turns high and R1 turns low.

Table 7-4 is valid for both half duplex and full duplex modes, and is independent of state of TERM_TX, TERM_RX and SLR pins.

INPUT	ENABLE	OUTI	PUTS	FUNCTION
L3	DIR	R2	R1	FUNCTION
Н	Н	Н	L	Actively drive bus high
L	Н	L	Н	Actively drive bus low
x	L	High impedance	High impedance	Driver disabled
x	OPEN	High impedance	High impedance	Driver disabled by default
OPEN	Н	Н	L	Actively drive bus high by default

Table 7-4. Driver Function Table

In full duplex mode, if \overline{SHDN} is high, receiver is always enabled. In half duplex mode, receiver is enabled if DIR = Low/floating and disabled if DIR = V_{IO}. When the differential input voltage defined as $V_{ID} = V_{R2} - V_{R1}$ or $V_{R3} - V_{R4}$ is higher than the positive input threshold, V_{TH+} , the receiver output, L2, turns high. When V_{ID} is lower than the negative input threshold, V_{TH-} , the receiver output, L2, turns low. If V_{ID} is between V_{TH+} and V_{TH-} the output is indeterminate.

Internal biasing of the receiver inputs causes the output to go failsafe-high when the transceiver is disconnected from the bus (open-circuit), the bus lines are shorted to one another (short-circuit), or the bus is not actively driven (idle bus).

In half duplex mode, when DIR is high, the receiver output is high-impedance and the magnitude and polarity of V_{ID} are irrelevant.

Table 7-5 is valid irrespective of state of TERM_TX, TERM_RX and SLR pins. Other logic outputs L1, L5, L7 and L8 remain high in RS-485 mode.

Table 7-5. Receiver Function Table

DIFFERENTIAL INPUT	OUTPUT	
$V_{ID} = V_{R2} - V_{R1}$ (Half duplex mode) or $V_{R3} - V_{R4}$ (Full duplex mode)	L2	FUNCTION
$V_{TH+} < V_{ID}$	Н	Receive valid bus high
V _{TH-} < V _{ID} < V _{TH+}	?	Indeterminate bus state
V _{ID} < V _{TH-}	L	Receive valid bus low
x	High impedance for DIR = V _{IO} in Half duplex mode	Receiver disabled in half duplex mode for DIR = V _{IO}
Open-circuit bus	Н	Fail-safe high output
Short-circuit bus	Н	Fail-safe high output
Idle (terminated) bus	Н	Fail-safe high output



7.4.2 RS-232 Functionality

In RS-232 mode, only way to disable driver is to go in shutdown mode by pulling SHDN pin low. A logic high at inputs for driver L3, L4 and L6 causes driver outputs R3, R4 and R6 to be driven low towards negative charge pump output V-. A logic low at inputs for driver L3, L4 and L6 causes driver outputs R3, R4 and R6 to be driven high towards positive charge pump output V+. If logic inputs are left floating due to the pull-up resistors on driver logic inputs, the driver outputs are driven low towards V-.

Table 7-6 is valid irrespective of the state of SLR pin.

INPUT	ENABLE	OUTPUTS	FUNCTION
L3, L4, L6	SHDN	R3, R4, R6	FUNCTION
н	Н	Low (driven towards V-)	Normal operation with inverting logic
L	Н	H (Driven towards V+)	Normal operation with inverting logic
Х	L	High impedance	TX and RX are disabled in shutdown mode
Open	Н	Low (driven towards V-)	Since pull-up on logic input pin, output driven low by default

 Table 7-6. Driver Function Table

For the RS-232 receiver, if the receiver bus inputs are above rising threshold V_{IT+} , corresponding received logic output goes low. Also, if the receiver bus inputs are below falling threshold V_{IT-} , corresponding received logic output goes high.

Table 7-7 is valid irrespective of the state of SLR pin.

 Table 7-7. Receiver Function Table

RS-232 BUS INPUT	LOGIC OUTPUT	FUNCTION
V_{IRx} (voltage on R1, R2, R5, R7 or R8)	L1, L2, L5, L7, L8	1 UNCTION
$V_{IT+} < V_{IRx}$	L	Normal operation with inverting logic
$V_{IT-} < V_{IRx} < V_{IT+}$?	Indeterminate bus state
V _{IRx} < V _{IT-}	Н	Normal operation with inverting logic
X	High impedance for SHDN = GND	Receiver disabled in shutdown mode
Open-circuit bus	Н	Fail-safe high output



7.4.3 Mode Control

RS-232 3T5R to RS-232 loopback mode transition and RS-232 loopback mode to RS-232 3T5R direct mode transition is not allowed. These 2 mode transitions must go through shutdown mode in between. Rest all combination of mode transitions are allowed.

MODE2	MODE1	MODE0	Operating mode	Function
X	Logic low	Logic low	RS-232 loopback, charge pump is ON, V+/V- are regulated	L3 reflects on L2/R2/R3; L4 reflects on L1/R4/R1; L6 reflects on L5, L7, L8, R5, R6, R7 and R8
X	Logic low	Logic high	RS-232 3T5R mode, charge pump is ON, V+/V- are regulated	3T5R mode; L3, L4, L6 are Logic inputs for RS232 driver; L1, L2, L5, L7, L8 are Logic outputs
x	Logic high	Logic low	RS-485 half duplex mode (charge pump is off)	L2 is RX Logic output; L3 is Driver Logic input; R1 R2 are Bus inverting and non-inverting terminals respectively
Logic low or float	Logic high	Logic high	RS-485 full duplex mode (charge pump is off)	R1R2 are inverting and non-inverting driver terminals; R3R4 are non- inverting and inverting receiver terminals.
Logic high	Logic high	Logic high	RS-485 loopback mode (charge pump is off)	R1, R2, R3, R4 continue to be bus terminals and reflect data on L3; DIR is don't care in this mode; TERM_RX not supported. External termination on R3/R4 not supported. R1/R2 can have internal or external termination.

Table 7-8. MODE Control Function Table



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

THVD4431 is a highly integrated multiprotocol transceiver supporting RS-232, RS-422 and RS-485 physical layer and is used for asynchronous data transmissions. MODE pins allow for the configuration of different operating modes. Device allows point-to-point RS-232 communication port and multipoint RS-485 communication port over common connector. The device also features integrated 120 Ω switchable termination resistor on RS-485 bus lines which enables same device to be used for middle nodes or end nodes in an RS-485 network. When the device is configured in RS-232 mode, RS-485 circuits and 120 Ω termination are disabled and do not interfere in RS-232 communication. For RS-232 communication, charge pump and 5k Ω resistor to ground on receiver bus pins is integrated in the device. This 5k Ω resistor and charge pump is automatically disabled in RS-485 mode. Slew rate limiting pin is provided so that same device can be used in slow speed or fast speed RS-485 and RS-232 applications. When ultra low power consumption is needed, device can be put in shutdown mode using SHDN pin. All these features make the device completely flexible and suitable for various application needs. Integration of termination resistor saves significant PCB area compared to discrete implementation.

8.2 Typical Application

An RS-485 bus consists of multiple transceivers connecting in parallel to a bus cable. To eliminate line reflections, each cable end is terminated with a termination resistor, R_T , whose value matches the characteristic impedance, Z_0 , of the cable. This method, known as parallel termination, generally allows for higher data rates over longer cable length.

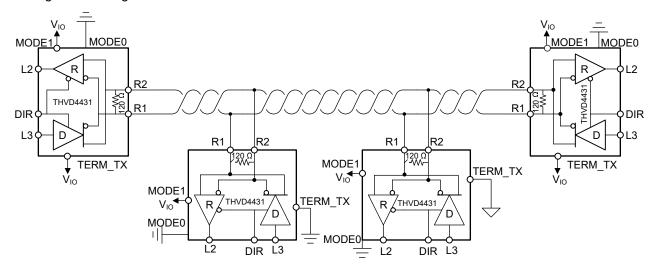


Figure 8-1. Typical RS-485 Network With Half-Duplex Transceivers

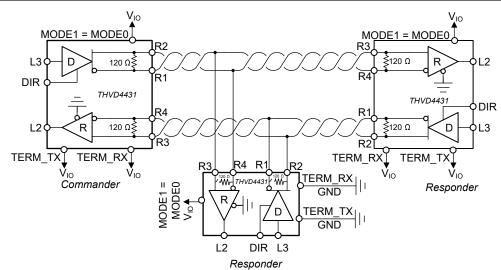


Figure 8-2. Typical RS-485 Network With Full-Duplex Transceivers

THVD4431 can be used in both networks (half and full duplex) and at all nodes (end node or middle nodes) since device has the configurability based on MODE2, MODE1, MODE0 pins and TERM_TX, TERM_RX pins.

THVD4431 also consists of three line drivers, five line receivers and dual charge pump circuit to enable RS-232 point-to-point serial communication. Full duplex transmission with hardware flow control is feasible with this device. This device provides the electrical interface between an asynchronous communication controller and the serial-port connector.



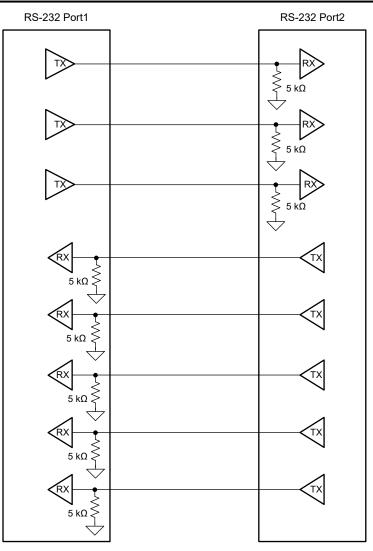


Figure 8-3. RS-232 serial communication

8.2.1 Design Requirements

RS-485 is a robust electrical standard suitable for long-distance networking that may be used in a wide range of applications with varying requirements, such as distance, data rate, and number of nodes. RS-232 is more suitable for debug or configuration point to point applications.

8.2.1.1 Data Rate and Bus Length for RS-485

There is an inverse relationship between data rate and cable length, which means the higher the data rate, the short the cable length. Conversely, the lower the data rate, the longer the cable length. While most RS-485 systems use data rates between 10 kbps and 100 kbps, some applications require data rates up to 250 kbps at distances of 4000 feet and longer. Longer distances are possible by allowing for small signal jitter of up to 5 or 10%.



(1)

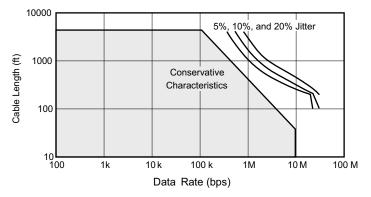


Figure 8-4. Cable Length vs Data Rate Characteristic

8.2.1.2 Stub Length for RS-485 Network

When connecting a node to the bus, the distance between the transceiver inputs and the cable trunk, known as the stub, should be as short as possible. Stubs present a non-terminated piece of bus line which can introduce reflections of varying phase as the length of the stub increases. As a general guideline, the electrical length, or round-trip delay, of a stub should be less than one-tenth of the rise time of the driver, thus giving a maximum physical stub length as shown in Equation 1.

$$L_{(STUB)} \le 0.1 \times t_r \times v \times c$$

where

- t_r is the 10/90 rise time of the driver
- *c* is the speed of light $(3 \times 10^8 \text{ m/s})$
- *v* is the signal velocity of the cable or trace as a factor of *c*

8.2.1.3 Bus Loading for RS-485 Network

The RS-485 standard specifies that a compliant driver must be able to drive 32 unit loads (UL), where 1 unit load represents a load impedance of approximately 12 k Ω . Because the THVD4431 in RS-485 half and full duplex mode consists of 1/8 UL transceivers which represents load resistance of approximately 96 kohm, connecting up to 256 receivers to the bus is possible for a limited common mode range of -7 V to 12 V.

8.2.2 Detailed Design Procedure

Figure 8-5 suggests an application schematic for THVD4431. The device has all logic pins on one side and bus side pins on other side to enable a flow-through layout in end application.



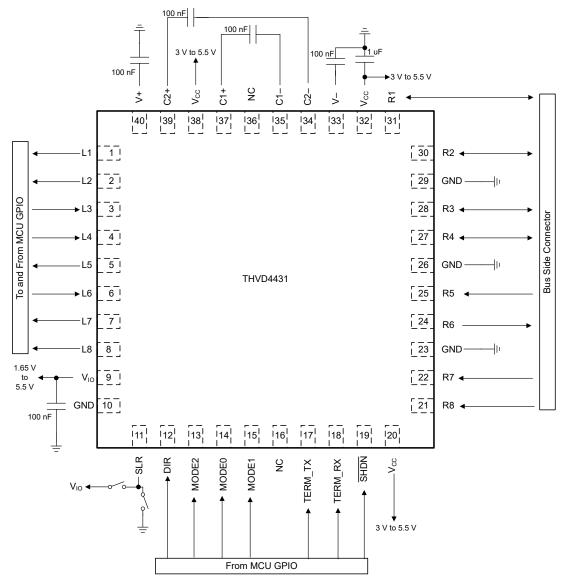
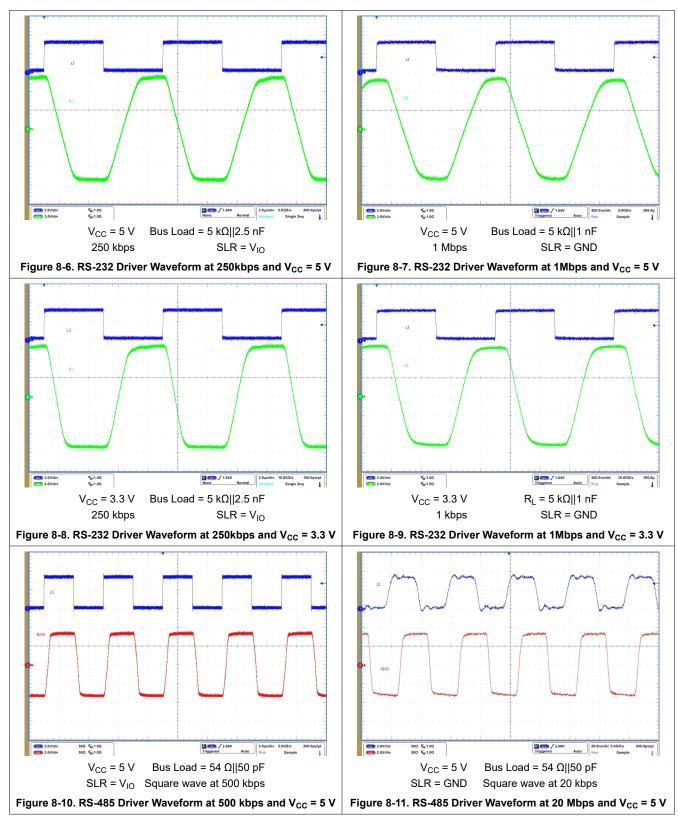


Figure 8-5. Typical application diagram for THVD4431

All V_{CC} power pins should have 1 μ F decoupling capacitor close to the respective device pins. RS-232 charge pump is designed such that 100 nF charge pump capacitors work for both 3.3 V and 5 V operating V_{CC} supply.

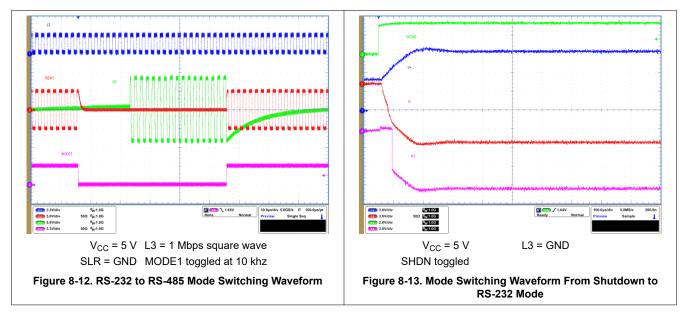


8.2.3 Application Curves





8.2.3 Application Curves (continued)



8.3 Power Supply Recommendations

For reliable operation at all data rates and supply voltages, each supply should be decoupled with a ceramic capacitor located as close to the supply pins as possible. Recommended bypass capacitor for V_{CC} is 1 μ F, for V_{IO} is 100 nF, for V+, V- charge pump voltage supplies is 100 nF. Besides this, two charge pump flying capacitors of 100 nF each are needed between C1+, C1- terminals and between C2+, C2- terminals. For V_{CC} = 3.3V ±10%, V+ and V- voltages are regulated to +5.5V and -5.5V typically. If an application needs larger RS-232 output voltages, V_{CC} = 5V ± 10% is recommended because V+ and V- are regulated to ±9.5V.



8.4 Layout

8.4.1 Layout Guidelines

Robust and reliable bus node design often requires the use of external transient protection devices to protect against surge transients that may occur in industrial environments. THVD4431 has integrated IEC ESD and EFT protection. So if the application does not need IEC Surge protection, external transient protection may not be needed. Since these transients have a wide frequency bandwidth (from approximately 3 MHz to 300 MHz), high-frequency layout techniques should be applied during PCB design.

- 1. Place the external protection circuitry close to the bus connector to prevent noise transients from propagating across the board.
- 2. Use V_{CC} and ground planes to provide low inductance. Note that high-frequency currents tend to follow the path of least impedance and not the path of least resistance.
- 3. Design the protection components into the direction of the signal path. Do not force the transient currents to divert from the signal path to reach the protection device.
- 4. Apply decoupling capacitors and charge pump capacitors as close as possible to the respective device pins such as V_{CC}, V_{IO}, V+, V-, C1+ to C1-, C2+ to C2- pins of transceiver.
- 5. Use at least two vias for V_{CC} and ground connections of decoupling capacitors and protection devices to minimize effective via inductance.
- 6. Optionally, use $1-k\Omega$ to $10-k\Omega$ pull-up and pull-down resistors for control lines to limit noise currents in these lines during transient events.



8.4.2 Layout Example

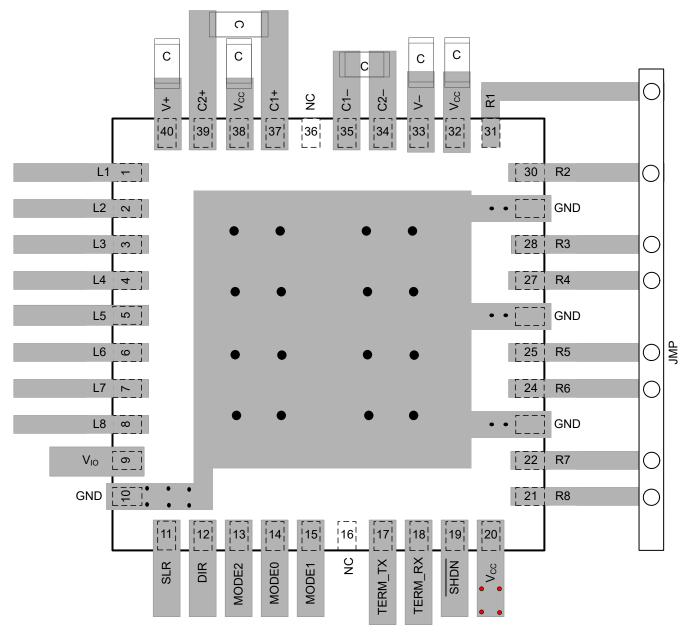


Figure 8-14. Layout Example



9 Device and Documentation Support

9.1 Device Support

9.1.1 Third-Party Products Disclaimer

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9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

С	hanges from Revision A (November 2023) to Revision B (April 2024)	Page
•	Changed values from nF to pF in Figure 5-15 and Figure 5-16	15

С	hanges from Revision * (August 2023) to Revision A (November 2023)	Page
•	Changed the document status from Advanced Information to Production data	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
THVD4431RHAR	ACTIVE	VQFN	RHA	40	4000	RoHS & Green	(6) NIPDAU	Level-1-260C-UNLIM	-40 to 125	THVD 4431	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All	dimensions	are	nominal	

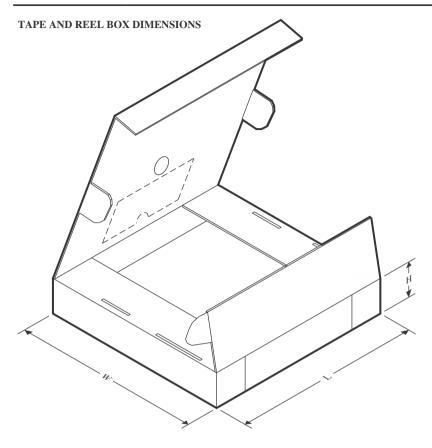
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THVD4431RHAR	VQFN	RHA	40	4000	330.0	16.4	6.3	6.3	1.1	12.0	16.0	Q2



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PACKAGE MATERIALS INFORMATION

25-Sep-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THVD4431RHAR	VQFN	RHA	40	4000	367.0	367.0	35.0

RHA 40

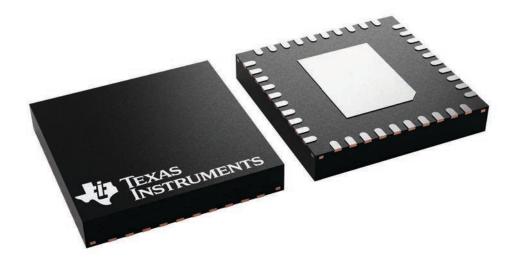
6 x 6, 0.5 mm pitch

GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





DATA BOOK PACKAGE OUTLINE

DRAFTER:	K. SINCERBOX	DATE:	09/01/2022				DIMENSIONS IN N	MILLIN	IETERS	
DESIGNER:		DATE:				🐌 Texas Instru	UMENTS	N	e identity Iumber	
CHECKER:	K. SINCERBOX	DATE:	09/01/2022			SEMICONDUCTOR OPE	ERATIONS	C)1295	
	It SINGERBOX		00/01/2022							
ENGINEER:	S. KUMMERL	DATE:	09/01/2022			ePOD, RHA0040R / VQFN,				
APPROVED:	D. CHIN & D. KAN	DATE:	09/01/2022			40 PIN, 0.5 M		,		
RELEASED:	K. SINCERBOX	DATE:	09/01/2022			,			-	
TEMPLATE IN	EO.	DATE:		SCALE	SIZE	40000	4	REV	PAGE	
	EDGE# 4218519	DATE.	04/07/2016	NTS	A	422900	1	A	1 of 5	

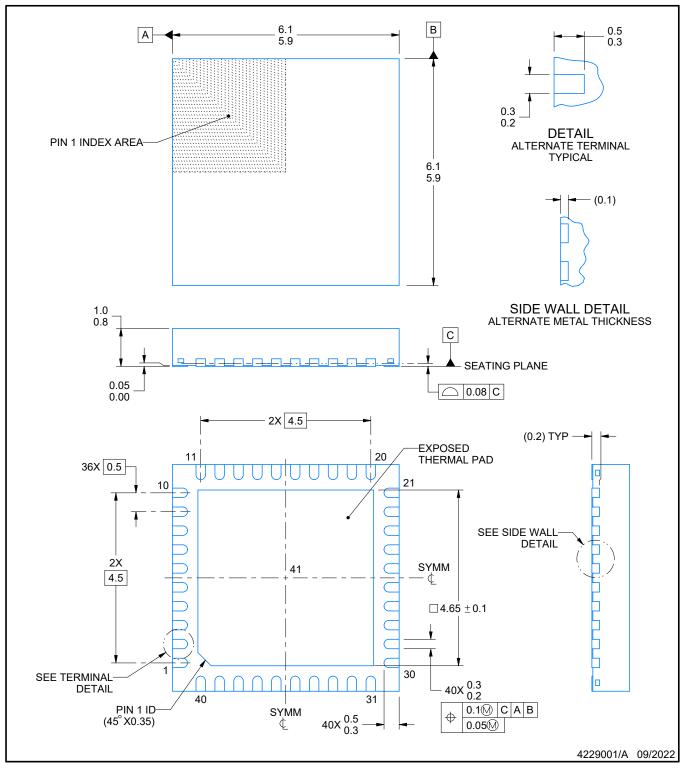
RHA0040R



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

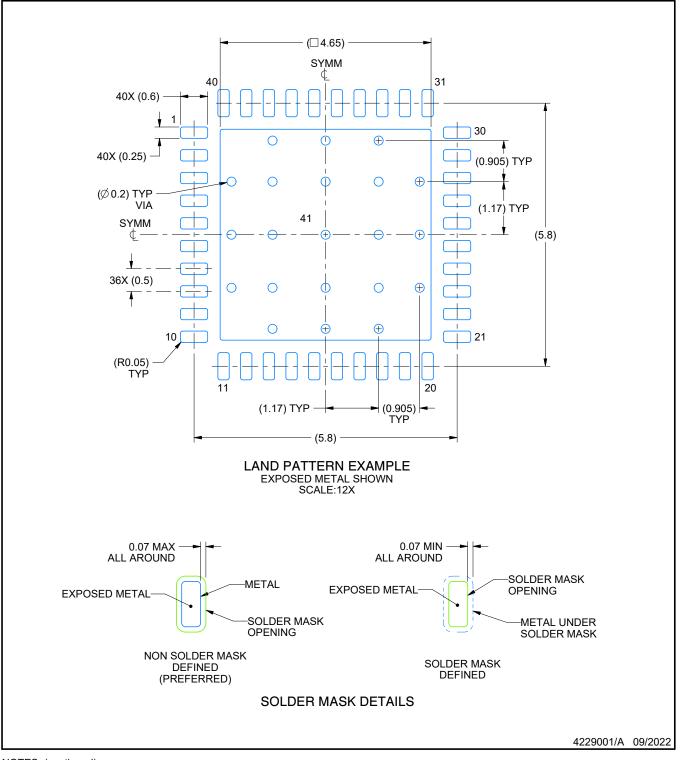


RHA0040R

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

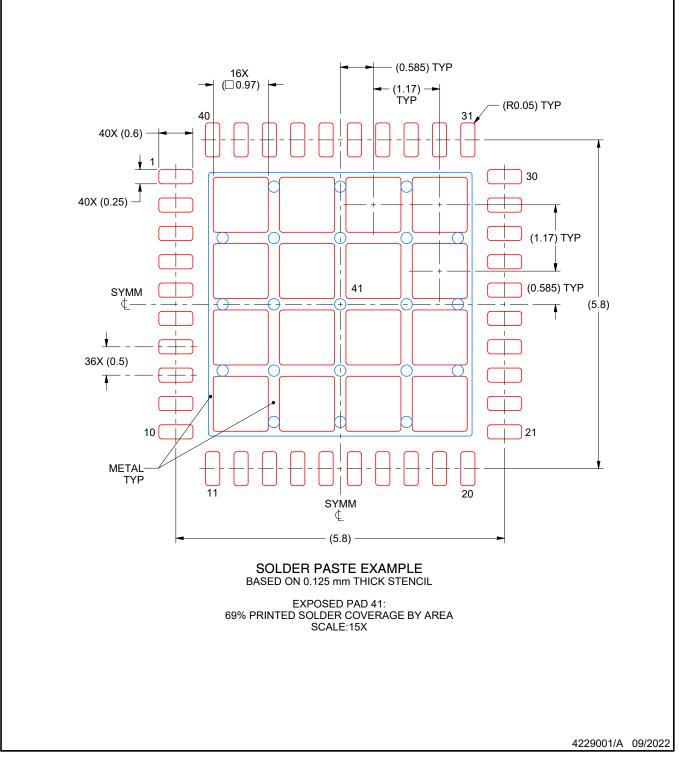


RHA0040R

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



	REVISIONS									
REV	DESCRIPTION	ECR	DATE	ENGINEER / DRAFTSMAN						
А	RELEASE NEW DRAWING	2201054	09/01/2022	S. KUMMERL / K. SINCERBOX						

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